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Power Semiconductors

2026-2027 Product Catalogue



MacMic Science & Technology Co., Ltd.

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MacMic Science & Technology Co., Ltd.



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COMPANY PROFILE

MACMIC was founded in 2006. Its main business is the R&D, manufacturing and sales of power semiconductor devices. The main products of MACMIC are IGBT, MOSFET, FRD, SiC, GaN chips, discrete devices and modules. MACMIC has advanced IGBT and FRD technologies. MACMIC focuses on becoming an expert in providing power semiconductor device solutions. The company is one of the leading companies in the power semiconductor industry in China. In 2021, MACMIC was successfully listed on the Shanghai Science and Technology Innovation Board with stock ticker 688711.



BUSINESS SCOPES

- ◆ Design, development, manufacturing, and marketing of new types of power semiconductor devices, i.e. IGBT, FRD, SiC, GaN chips and discrete devices, standard and customer-specific power modules (CSPM).

QUALITY MANAGEMENT SYSTEMS

- ◆ Insisting on independent innovation, scientific management and continuous improvement, providing better products and services to meet and exceed customers' requirements and expectations.
- ◆ The entire production process is managed by the ISO9001 and IATF16949 quality management systems. Every process is strictly checked and tested to ensure the quality and stability of the products.

COMPANY GOALS

- ◆ Independent innovation, design, development and manufacturing of world-class IGBT, FRD, SiC, GaN discretes and modules, to provide solutions of power semiconductor devices.



COMPANY STRENGTH

POWER MODULE FABRICATION LINES

Fab 1 (Huashan Plant)	—Plant Area: 6000m ² ,	Clean Room Area: 1700m ²
Fab 2 (Xinzhu Plant)	—Plant Area: 11200m ² ,	Clean Room Area: 5600m ²
Fab 3 (Xinzhu Plant)	—Plant Area: 12000m ² ,	Clean Room Area: 7500m ²
Fab 4 (Core Energy*)	—Plant Area: 14000m ² ,	Clean Room Area: 12300m ²

* Note: Core Energy is a subsidiary of MacMic.

CHARACTERISTIC ANALYSIS LABORATORY

- Diode Reverse Recovery Tester
- IGBT Static Parameter Tester
- IGBT Switching Parameter Tester
- IGBT Charge Tester
- IGBT Short Circuit Tester
- HV Static Parameter Tester
- UIS Tester
- Surge Current Tester
- Electrostatic Discharge Tester
-

RELIABILITY LABORATORY

- High Temperature Reverse Bias Tester
- High Temperature Gate Bias Tester
- Power Cycle Tester
- High / Low Temperature Cycle Tester
- 85 / 85 Temperature / Humidity Tester
- High Humidity High Temperature Reverse Bias Tester
- High Temperature Storage Life Tester
- Low Temperature Storage Life Tester
- Thermal Shock Tester
- Salt Spray Evaluation Tester
- Vibration Evaluation Test
- Mechanical Shock Tester
- Highly Accelerated Stress Tester

FAILURE ANALYSIS LABORATORY

- Digital Microscope
- Scanning Acoustic Microscope
- Scanning Electron Microscope (SEM)
- Ion Milling System
- Thermal EMMI
- Laser Decap
- Automatic Cutting Machine
- Automatic Grinder and Polisher

Macro Ambitions Achieved
through Micro Steps



IGBT MODULES

Ranges

- 600-2300V / 10-1200A

Packages

- GB, GC, GCB, GCE, GCF, GD, GEB, GH, GHB, GHC, GHD, GHP, GJ, GK, GQ, GQC, GS, GV, GVB, GVC, GVD, GVE, GVF, GW, GWB, GWD, GWJ

Circuit Configurations

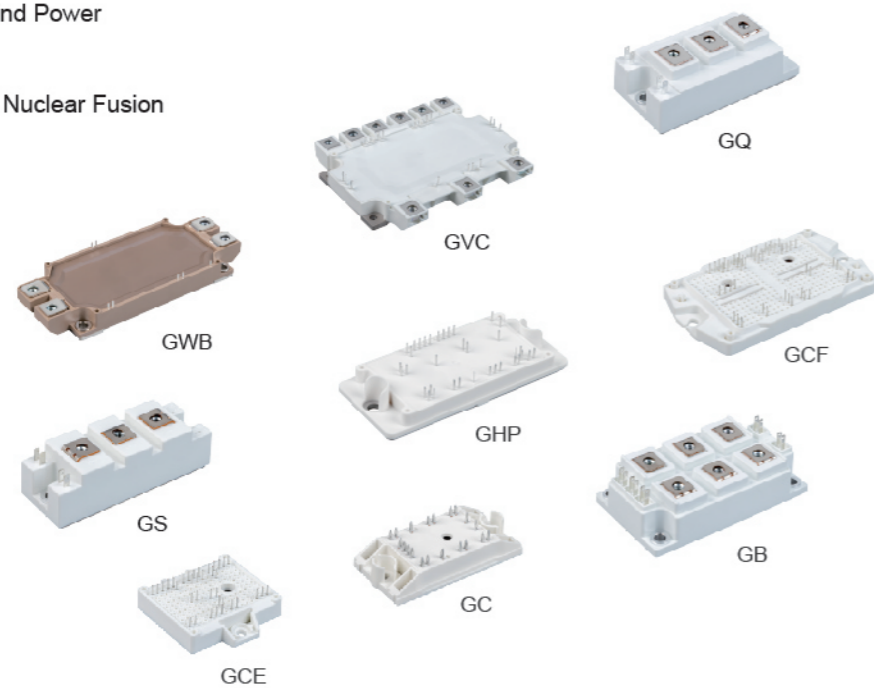
- Single Circuit
- Half-Bridge Circuit, Full-Bridge Circuit, Three Phase Bridge Circuit
- Chopping Circuit, Common-Emitter Circuit
- Three-Level Circuit

Features

- Fast Switching Speed
- Low Conduction Loss
- Soft Turn-Off Characteristic
- High Short Circuit Capability

Applications

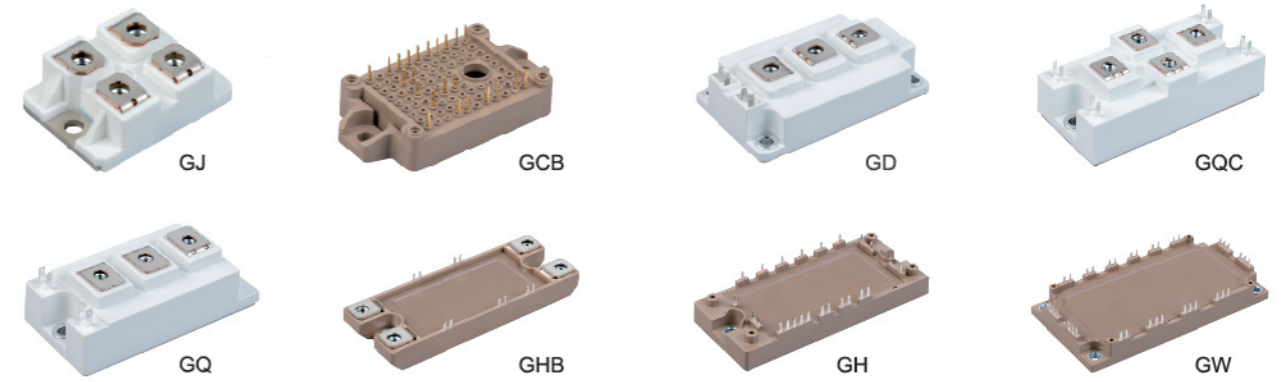
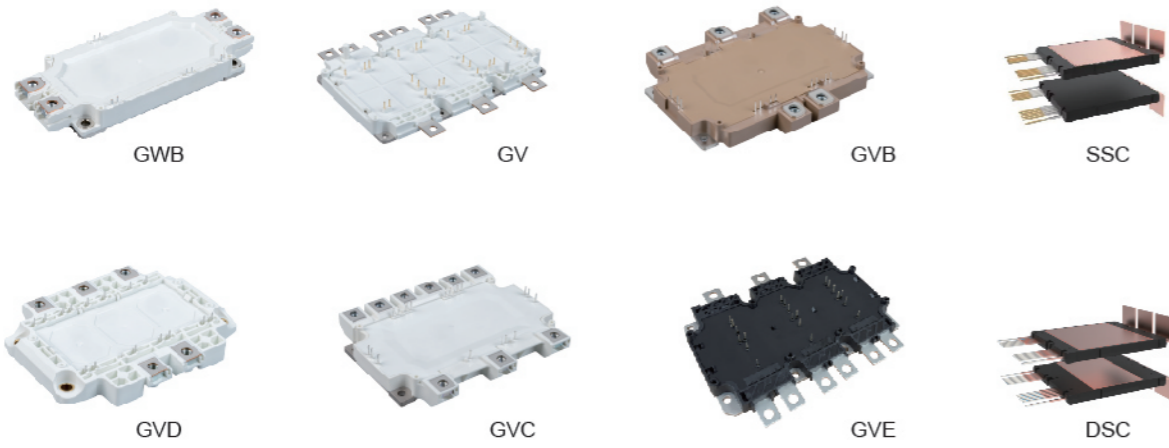
- Welding Machine, Cutting Machine
- Plating Power Supply, Induction Heating
- UPS, Inverter, Chopper
- Servo Drive, Switched Reluctance Drive
- Solar Inverter, Wind Power
- Electric Vehicle
- AIDC, Controlled Nuclear Fusion



600-650V IGBT MODULES

Circuit	Part Number	V _{CES} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thJC} max. (K/W)	T _{jmax}	Package Outline
<p>PD</p>	M3i						
	MMG150B065PD6TC	650	150	1.55	0.34	150°C	GB
	MMG200B065PD6TC	650	200	1.55	0.25	150°C	GB
	MMG300B065PD6TC	650	300	1.55	0.17	150°C	GB
	MMG100CE065PD6TC	650	100	1.55	0.45	150°C	GCE
	MMG75S060B6TC	600	75	1.55	0.60	150°C	GS
	MMG100S060B6TC	600	100	1.55	0.45	150°C	GS
	MMG150S060B6TC	600	150	1.65	0.34	150°C	GS
	MMG200S060B6TC	600	200	1.55	0.25	150°C	GS
	MMG300Q060B6TC	600	300	1.55	0.17	150°C	GQ
<p>B</p>	MMG300D060B6TC	600	300	1.55	0.17	150°C	GD
	MMG400D060B6TC	600	400	1.55	0.125	150°C	GD
	M5i						
	MMG200CE065PD6T5	650	200	1.50	0.32	150°C	GCE
	M6i						
	MMG150CE065PD6T6	650	150	1.40	0.40	150°C	GCE





◆ 750V IGBT MODULES

Circuit	Part Number	V _{CE(sat)} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thjC} max. (K/W)	T _{jmax}	Package Outline
	MMG280VD075X6T7	750	280	1.38	0.252	175°C	GVD
	MMG400VD075X6TC-12	750	400	1.40	0.146	150°C	GVD
	MMG400VB075X6TC	750	400	1.21	0.107	150°C	GVB
	MMG400VC075X6TC	750	400	1.21	0.14	150°C	GVC
	MMG600V075X6T7	750	600	1.10	0.16	175°C	GV
	MMG820V075X6T7	750	820	1.10	0.12	175°C	GV
	MMG950V075X6T7	750	950	1.15	0.10	175°C	GV
	MMG770VE075X6T7	750	770	1.20	0.16	175°C	GVE
	MMG880VE075X6T7	750	880	1.00	0.14	175°C	GVE
	MMG500VF075X6T7	750	500	1.28	0.33	175°C	GVF
	CS095HB08C1P1-I7000 *	750	950	1.24	0.133	175°C	DSC
	CS080HB08C1P1-I7000*	750	800	1.22	0.132	175°C	DSC
	CS054HB08C2P1-Z7000*	750	540	1.22	0.358	175°C	SSC

◆ 1200V IGBT MODULES

Circuit	Part Number	V _{CE(sat)} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thjC} max. (K/W)	T _{jmax}	Package Outline
	M3i						
	MMG50S120B6UC	1200	50	1.70	0.37	150°C	GS
	MMG75S120B6UC	1200	75	1.70	0.28	150°C	GS
	MMG100S120B6UC	1200	100	2.20	0.27	150°C	GS
	MMG150S120B6UC	1200	150	2.00	0.15	150°C	GS
	MMG150D120B6UC	1200	150	1.70	0.16	150°C	GD
	MMG200D120B6UC	1200	200	1.90	0.14	150°C	GD
	MMG300D120B6UC	1200	300	1.90	0.095	150°C	GD
	MMG50QC120H6UC	1200	50	1.70	0.37	150°C	GQC
	MMG75QC120H6UC	1200	75	1.70	0.28	150°C	GQC
	MMG10CB120XB6TC	1200	10	1.85	1.25	150°C	GCB
	MMG10CB120X6TC	1200	10	1.85	1.25	150°C	GCB
	MMG15CB120XB6TC	1200	15	1.85	1.05	150°C	GCB
	MMG25CE120XB6TC	1200	25	1.85	0.75	150°C	GCE
	MMG35CE120XB6TC	1200	35	1.85	0.60	150°C	GCE
	MMG25HD120XB6TC	1200	25	1.85	0.90	150°C	GHD

* Note: Transfer-Molded IGBT Modules by Core Energy



GQ



GWJ



GCB



GHE

◆ 1200V IGBT MODULES

Circuit	Part Number	V _{CES} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thJC} max. (K/W)	T _{jmax} (°C)	Package Outline
	MMG35HD120XB6TC	1200	35	1.85	0.72	150°C	GHD
	MMG35HD120XT6TC	1200	35	1.85	0.72	150°C	GHD
	MMG50HD120XB6TC	1200	50	1.80	0.54	150°C	GHD
	MMG50HD120XT6TC	1200	50	1.80	0.54	150°C	GHD
	MMG25H120XB6TC	1200	25	1.85	0.90	150°C	GH
	MMG40H120XB6TC	1200	40	1.95	0.72	150°C	GH
	MMG50W120XB6TC	1200	50	1.85	0.54	150°C	GW
	MMG75W120XB6TC	1200	75	1.85	0.39	150°C	GW
	MMG75WD120XB6TC	1200	75	1.85	0.39	150°C	GWD
	MMG100WD120XB6TC	1200	100	1.70	0.29	150°C	GWD
	MMG75H120X6TC	1200	75	1.85	0.39	150°C	GH
	MMG75W120X6TC	1200	75	1.85	0.39	150°C	GW
	MMG100W120X6TC	1200	100	1.85	0.29	150°C	GW
	MMG150W120X6TC	1200	150	1.85	0.20	150°C	GW
	MMG75J120UZ6TC	1200	75	1.85	0.39	150°C	GJ
	MMG75J120U6TC	1200	75	1.85	0.39	150°C	GJ
	MMG100J120UZ6TC	1200	100	1.85	0.29	150°C	GJ
	MMG150J120UZ6TC	1200	150	1.85	0.20	150°C	GJ
	MMG75S120B6TC	1200	75	1.85	0.39	150°C	GS
	MMG100S120B6TC	1200	100	1.70	0.29	150°C	GS
	MMG150S120B6TC	1200	150	1.85	0.20	150°C	GS
	MMG150D120B6TC	1200	150	1.70	0.19	150°C	GD

◆ 1200V IGBT MODULES

Circuit	Part Number	V _{CES} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thJC} max. (K/W)	T _{jmax} (°C)	Package Outline
	MMG200Q120B6TC	1200	200	1.70	0.14	150°C	GQ
	MMG200D120B6TC	1200	200	1.70	0.14	150°C	GD
	MMG300D120B6TC	1200	300	1.85	0.10	150°C	GD
	MMG400D120B6TC	1200	400	1.85	0.75	150°C	GD
	MMG450D120B6TC	1200	450	1.85	0.07	150°C	GD
	MMG300WB120B6TC	1200	300	1.80	0.094	150°C	GWB
	MMG450WB120B6TC	1200	450	1.85	0.065	150°C	GWB
	MMG300WB120TLA6TC	1200	300	1.80	0.10	150°C	GWB
	MMG300WB120TLB6TC	1200	300	1.80	0.10	150°C	GWB
	M6i						
	MMG600WB120B6T6	1200	600	1.70	0.051	150°C	GWB
	M7i						
	MMG10CB120XB6T7	1200	10	1.52	2.05	175°C	GCB
	MMG10CB120XB6T7_Y2	1200	10	1.52	2.05	175°C	GCB
	MMG15CB120XB6T7	1200	15	1.52	1.80	175°C	GCB
	MMG15CB120XB6T7_Y2	1200	15	1.52	1.80	175°C	GCB
	MMG25CB120XB6T7	1200	25	1.54	0.79	175°C	GCB
	MMG25CB120X6T7	1200	25	1.52	0.48	175°C	GCB
	MMG25CB120X6T7_Y2	1200	25	1.52	0.48	175°C	GCB
	MMG25CE120X6T7	1200	25	1.52	0.48	175°C	GCE
	MMG25CE120XB6T7	1200	25	1.52	0.48	175°C	GCE
	MMG25CE120XB6T7_Y2	1200	25	1.52	0.48	175°C	GCE
	MMG35CB120X6T7	1200	35	1.52	1.65	175°C	GCB
	MMG35CE120XB6T7	1200	35	1.52	1.65	175°C	GCE
	MMG35CE120XB6T7_Y2	1200	35	1.52	1.65	175°C	GCE

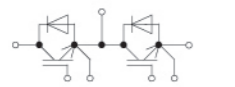


◆ 1200V IGBT MODULES

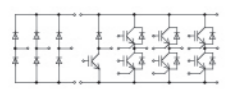
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	MMG50CE120XB6T7	1200	50	1.52	0.44	175	GCE
	MMG50CE120XT6T7	1200	50	1.52	0.44	175	GCE
	MMG50CE120XB6T7_Y2	1200	50	1.52	0.44	175	GCE
	MMG50HD120XB6T7	1200	50	1.52	0.579	175	GHD
	MMG50HD120XB6T7_Y1	1200	50	1.52	0.579	175	GHD
	MMG75HE120XB6T7_W11	1200	75	1.48	0.44	175	GHE
	MMG75CE120X6T7	1200	75	1.52	0.44	175	GCE
	MMG75CE120X6T7_Y2	1200	75	1.52	0.44	175	GCE
	MMG75HE120XB6T7	1200	75	1.52	0.44	175	GHE
	MMG75HE120XB6T7_Y1	1200	75	1.52	0.44	175	GHE
	MMG100WD120XB6T7	1200	100	1.52	0.373	175	GWD
	MMG100WD120XB6T7_Y1	1200	100	1.52	0.373	175	GWD
	MMG150WJ120XB6T7	1200	150	1.45	0.17	175	GWJ
	MMG150WJ120XB6T7_Y1	1200	150	1.45	0.17	175	GWJ
	MMG200W120X6T7	1200	200	1.50	0.249	175	GW
	MMG225WB120B6T7	1200	225	1.52	0.147	175	GWB
	MMG300VB120X6T7	1200	300	1.60	0.148	175	GVB
	MMG300WB120B6T7	1200	300	1.52	0.119	175	GWB
	MMG450WQ120PD6T7	1200	450	1.55	0.107	175	GWQ
	MMG450WQ120PD6T7H	1200	450	1.60	0.107	175	GWQ
	MMG450WB120B6T7	1200	450	1.52	0.0875	175	GWB
	MMG500W120PD6T7	1200	500	1.67	0.107	175	GW
	MMG500W120PD6T7H	1200	500	1.67	0.107	175	GW
	MMG560WQ120BF6T7	1200	560	1.58	0.09	175	GWQ
	MMG560WQ120BF6T7S	1200	560	1.50	0.09	175	GWQ
	MMG600WB120B6T7	1200	600	1.52	0.0721	175	GWB
	MMG800WB120B6T7	1200	800	1.52	0.052	175	GWB
	MMG800D120B6T7	1200	800	1.60	0.051	175	GD



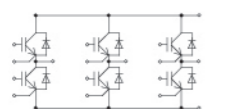
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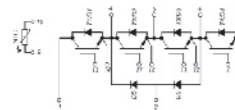
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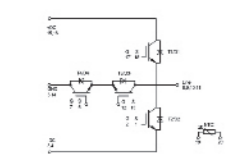
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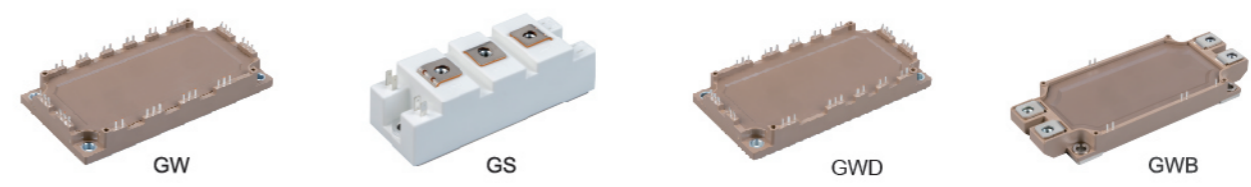
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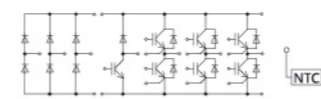


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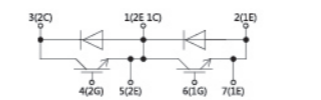


◆ 1700V IGBT MODULES

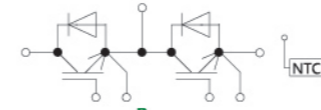
Circuit	Part Number	V _{CE(s)} min. (V)	I _c (A)	V _{CE(sat)} typ. (V)	R _{thJC} max. (K/W)	T _{jmax} (°C)	Package Outline
	M3i						
	MMG75W170X6TC	1700	75	2.15	0.26	150	GW
	MMG100W170X6TC	1700	100	2.40	0.21	150	GW
	MMG75WD170XB6TC	1700	75	2.15	0.27	150	GWD
	MMG75S170B6TC	1700	75	2.15	0.27	150	GS
	MMG100S170B6TC	1700	100	2.15	0.22	150	GS
	MMG150D170B6TC	1700	150	2.15	0.14	150	GD
	MMG200D170B6TC	1700	200	2.20	0.10	150	GD
	MMG300D170B6TC	1700	300	2.15	0.085	150	GD
	MMG300WB170B6TC	1700	300	2.15	0.09	150	GWB
	MMG450WB170B6TC	1700	450	2.00	0.053	150	GWB
	MMG75W170HX6TC	1700	75	2.15	0.30	150	GW
	MMG100W170HX6TC	1700	100	2.20	0.20	150	GW
	MMG150W170HX6TC	1700	150	2.20	0.17	150	GW
	M6i						
	MMG600WB170B6T6	1700	600	1.70	0.039	150	GWB



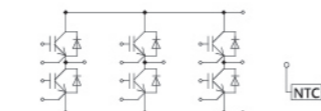
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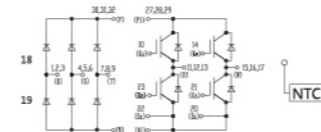
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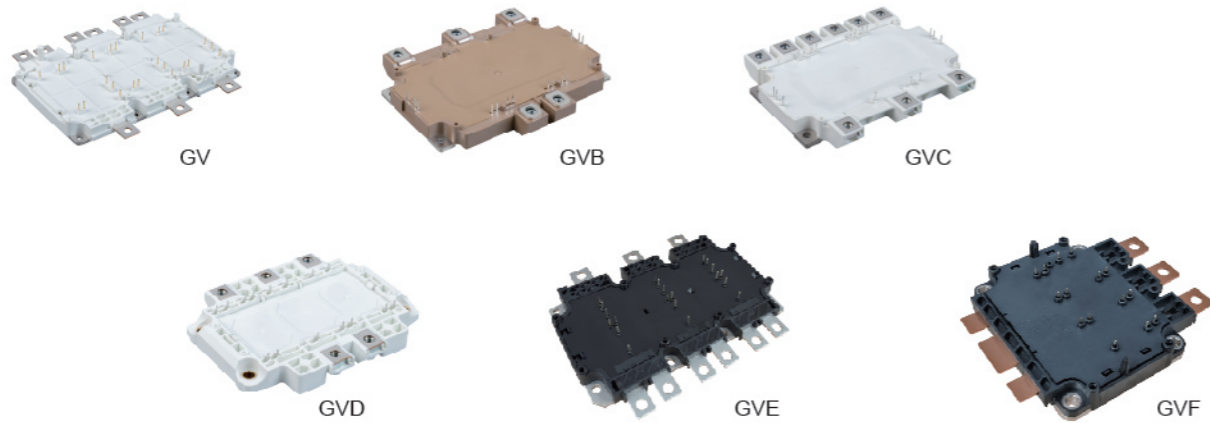


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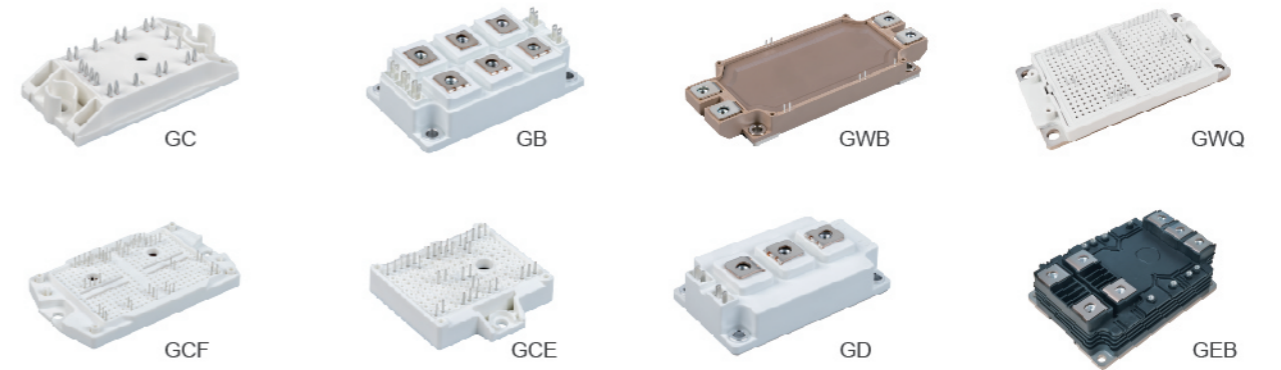
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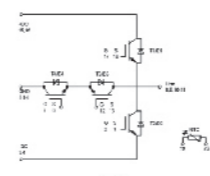


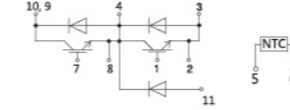
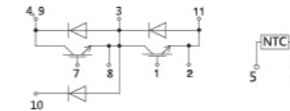


◆ IGBT MODULES FOR ELECTRIC VEHICLES

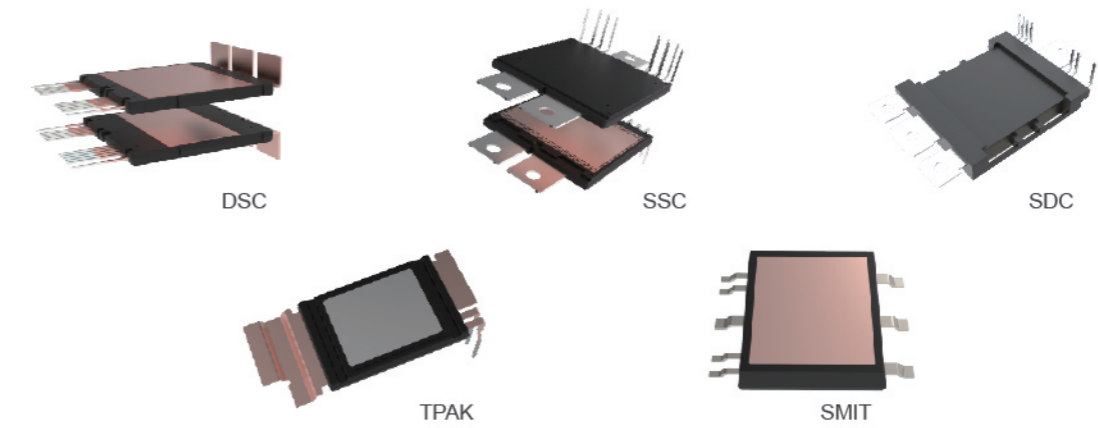
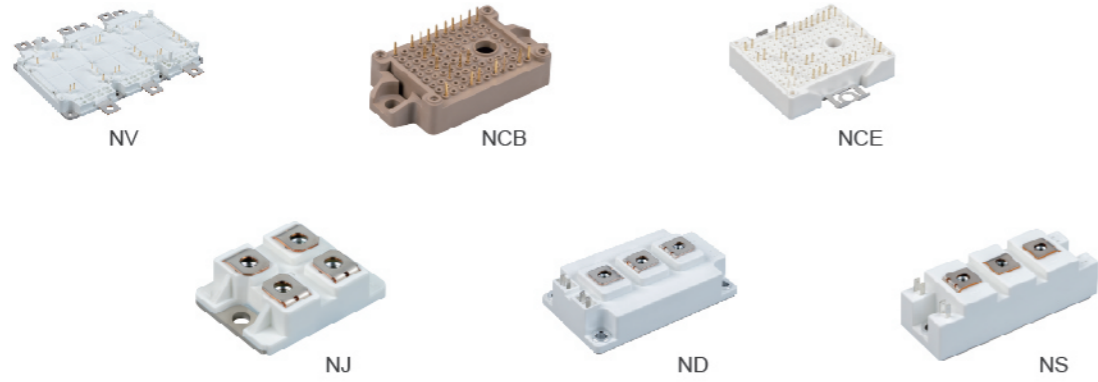
Circuit	Part Number	V _{CE(sat)} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thJC} max. (K/W)	T _{jmax}	Package Outline
	MMG450WB120B6TC	1200	450	1.85	0.065	150°C	GWB
	MMG600WB120B6T6_W11	1200	600	1.70	0.051	150°C	GWB
	MMG800WB120B6T7_W11	1200	800	1.80	0.04	175°C	GWB
	MMG280VD075X6T7	750	280	1.38	0.252	175°C	GVD
	MMG400VD075X6TC-12	750	400	1.40	0.146	150°C	GVD
	MMG400VB075X6TC	750	400	1.21	0.107	150°C	GVB
	MMG400VC075X6TC	750	400	1.21	0.14	150°C	GVC
	MMG600V075X6T7	750	600	1.10	0.16	175°C	GV
	MMG820V075X6T7	750	820	1.10	0.12	175°C	GV
	MMG950V075X6T7	750	950	1.15	0.10	175°C	GV
	MMG600V120X6T7	1200	600	1.38	0.10	175°C	GV
	MMG770VE075X6T7	750	770	1.20	0.16	175°C	GVE
	MMG880VE075X6T7	750	880	1.00	0.14	175°C	GVE
	MMG500VF075X6T7	750	500	1.28	0.33	175°C	GVF



◆ IGBT MODULES FOR RENEWABLE ENERGY

Circuit	Part Number	V _{CE(sat)} min. (V)	I _C (A)	V _{CE(sat)} typ. (V)	R _{thJC} max. (K/W)	T _{jmax}	Package Outline
	MMG80C120BF_Y1	1200	80	1.90	0.50	150°C	GC
	MMG150B065PD6TC	650	150	1.55	0.34	150°C	GB
	MMG500W120PD6T7	1200	500	1.67	0.107	175°C	GW
	MMG500W120PD6T7H	1200	500	1.67	0.107	175°C	GW
	MMG450WB120B6TC	1200	450	1.85	0.065	150°C	GWB
	MMG450WB170B6TC	1700	450	2.00	0.053	150°C	GWB
	MMG600WB120B6T6	1200	600	1.70	0.051	150°C	GWB
	MMG600WB170B6T6	1700	600	1.70	0.039	150°C	GWB
	MMG800WB120B6T6	1200	800	1.80	0.04	150°C	GWB
	MMG800WB120B6T7_W11	1200	800	1.50	0.039	175°C	GWB
	MMG300WB120TLB6TC	1200	300	1.80	0.10	150°C	GWB
	MMG300WB120TLA6TC	1200	300	1.80	0.10	150°C	GWB
	MMG150CE065PD6T6	650	150	1.40	0.40	150°C	GCE
	MMG200CE065PD6T5	650	200	1.50	0.32	150°C	GCE
	MMG200CE065PD6T5S	650	200	1.50	0.32	150°C	GCE
	MMG800D120B6T7	1200	800	1.60	0.051	175°C	GD
	MMG200WQ100BT6T7H	1000	200	1.60	0.279	175°C	GWQ
	MMG450WQ120PD6T7	1200	450	1.55	0.107	175°C	GWQ
	MMG450WQ120PD6T7H	1200	450	1.60	0.107	175°C	GWQ
	MMG560WQ120BF6T7	1200	560	1.58	0.09	175°C	GWQ
	MMG560WQ120BF6T7S	1200	560	1.50	0.09	175°C	GWQ
	MMG600WQ100PD6T7	1000	600	1.80	0.097	175°C	GWQ
	MMG600WQ100PD6T7H	1000	600	1.80	0.097	175°C	GWQ
	MMG1200EB230B6T7	2300	1200	1.90	0.0185	175°C	GEB

SiC MODULES



◆ SiC MOSFET MODULES

Circuit	Part Number	V _{DSS} (V)	I _D (A)	R _{DS(on)} (mΩ)	R _{thJF} /R _{thJC} (K/W)	T _{jmax} (°C)	Package Outline
	MMN02V120X6BS	1200	439	2	0.118	175°C	NV
	MMN01V120X6BS	1200	540	1	0.105	175°C	NV
	MMN15S120BC2P6NA	1200	80	15	0.467	175°C	NS
	MMN15S120BC2P6NA-H	1200	75	15	0.66	175°C	NS
	MMN7CB120BA6BS	1200	100	7	0.32	175°C	NCB
	MMN7CB120BA4P6NA	1200	100	7	0.36	175°C	NCB
	MMN4CE120BA4P6BS	1200	200	4	0.32	175°C	NCE
	MMN13J120U6NA	1200	108	13	0.565	175°C	NJ
	MMN08D120BC4P6NA	1200	120	8	0.27	175°C	ND
	MMN07D170BC3P6BS_F	1700	135	7	0.175	175°C	ND

◆ TRANSFER-MOLDED SiC MODULES

Circuit	Part Number	V _{DSS} (V)	I _D (A)	R _{DS(on)} (mΩ)	R _{thJF} /R _{thJC} (K/W)	T _{jmax} (°C)	Package Outline
	CC002HB12C5C1-E3000	1200	1000	1.6	0.068	175°C	DSC
	CC001HB12C1P1-R4000	1200	1200	1.4	0.061	175°C	SSC
	CC002HB12C3P1-B2000	1200	480	2.1	0.0904	175°C	SDC
	CC010ST12F1C1-F1000	1200	200	2.2	0.10	175°C	Tpak
	CC008ST12F1C1-F1000	1200	250	8	0.095	175°C	Tpak
	CC060HB12S1C1-F1000	1200	25	60	0.50	175°C	SMIT
	CC035HB12S1C1-F1000	1200	40	35	0.27	175°C	SMIT

Note: Transfer-Molded SiC Modules by Core Energy

SiC DISCRETES



TO-247-2L



TO-247-4L



TO-263-7L

SiC SBD DISCRETES

Circuit	Part Number	V_{RRM} (V)	$I_{F(AV)}$ (A)	V_F (V)	I_{FSM} (A)	T_{jmax}	Qualification	Package Outline
	MM20S120B	1200	20	1.40	180	175°C	Industrial	TO-247-2L
	MM20SH120B	1200	20	1.44	180	175°C	Industrial	TO-247-2L
	MM40S120B	1200	40	1.40	360	175°C	Industrial	TO-247-2L
	MM40SH120B	1200	40	1.41	400	175°C	Industrial	TO-247-2L

SiC MOSFET DISCRETES

Circuit	Part Number	V_{DSS} (V)	I_D (A)	$R_{DS(on)}$ (mΩ)	Q_q (nC)	T_{jmax}	Qualification	Package Outline
	MML30N3S120BK	1200	65	30	102	175°C	Industrial	TO-247-4L
	MMQ30N3S120BK	1200	65	30	102	175°C	Automotive	TO-247-4L
	MMQ13N3S120BK	1200	149	13	185	175°C	Automotive	TO-247-4L
	MML13N3S120BK	1200	149	13	185	175°C	Industrial	TO-247-4L
	MMQ30N3S120SJ	1200	75	30	102	175°C	Automotive	TO-263-7L
	MML30N3S120SJ	1200	75	30	102	175°C	Industrial	TO-263-7L

GaN HEMT POWER DEVICES

Ranges

- 100-650V / 2.3-90mΩ

Packages

- QFN, TOLL, TOLT, WLCSP

Applications

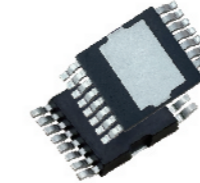
- Server Power Supply, Electric Vehicle, Inverter
- Humanoid Robot, Drone

Features

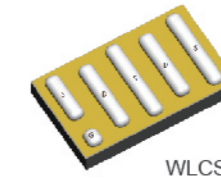
- Ultra High Switching Frequency
- No Reverse-recovery Charge
- Low Gate Charge, Low Output Charge



TOLL



TOLT



WLCSP

Circuit	Part Number	Configuration	V_{DS} max (V)	$R_{DS(on)}$ typ (mΩ)	$R_{DS(on)}$ max (mΩ)	Q_{oss} (nC)	ID max (A)	ID pulse max (A)	Package Outline
	ASL025HG65TL	Single	650	20	25	220	72	130	TOLL
	ASL030HG65TL	Single	650	27	30	225	60	100	TOLL
	ASL050HG65TL	Single	650	45	50	150	40	70	TOLL
	ASL060HG65TL	Single	650	60	70	60	32	50	TOLL
	ASL075HG65TL	Single	650	75	90	50	24	32	TOLL
	ASL010HG10WB	Single	100	8	10	48	16	130	WLCSP 4.15x6.8
	ASL007HG10WB	Single	100	5.5	7	25	19	137	WLCSP 2.5x1.5
	ASL004H2G10WB	Single	100	3.1	4	27	29	165	WLCSP 2.5x1.5
	ASL002H2G10QX	Single	100	1.7	2.3	71	58	453	QFN 5x3

FRD MODULES

Ranges

- 200-1200V / 120-800A

Circuit Configuration

- Non-insulated Common-Cathode Circuit
- Insulated Common-Cathode Circuit
- Insulated Common-Anode Circuit
- Insulated Half Bridge Circuit

Applications

- Welding Machine
- SMPS, UPS
- Inverter, Chopper
- PFC

Packages

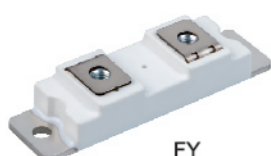
- FD, FJ, FN, FS, FY, FYB, FZ

Features

- Short Recovery Time
- Soft-Recovery Characteristics
- Low Reverse Recovery Charge
- Low Forward Voltage
- High Avalanche Energy
- Stressless Package



FZ



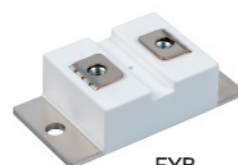
FY



FN



FJ



FYB



FS



FD



DK1
(Non-insulated)

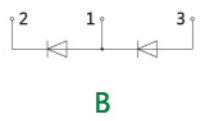




U



U

Circuit	Part Number	V _{RRM} (V)	I _{F(AV)} (A)	I _{FSM} (A)	V _{FM@I_{FM}} (V)	I _{FM} (A)	t _{rr} (ns)	R _{thJC} (K/W)	Package Outline
	MMF200ZB040DK1	400	2×100	1250	1.00	100	70	0.20	FZ
	MMF200ZB040DK1C	400	2×100	1000	1.10	100	75	0.22	FZ
	MMF200ZB040DK1D	400	2×100	700	1.25	100	49	0.37	FZ
	MMF800Y020DK1	200	2×400	3000	1.00	400	165	0.08	FY
	MMF200Y040DK1	400	2×100	1250	1.00	100	70	0.10	FY
	MMF300Y040DK1B	400	2×150	1900	1.20	150	65	0.10	FY
	MMF400Y040DK1	400	2×200	2550	1.20	200	75	0.08	FY
	MMF400Y040DK1B	400	2×200	2550	1.20	200	75	0.08	FY
	MMF200Y060DK1	600	2×100	1200	1.20	100	91	0.20	FY
	MMF300Y060DK1	600	2×150	2500	1.20	150	100	0.08	FY
	MMF300YB050U	500	300	3800	1.20	300	160	0.11	FYB
	MMF300YB070U	700	300	3800	1.38	300	121	0.12	FYB
	MMF600S060U	600	600	4800	1.15	600	175	0.075	FS
	MMF300S120U	1200	300	2500	2.75	300	150	0.14	FS
	MMF400S120U	1200	400	3200	3.00	400	180	0.11	FS
	MMF600S120U	1200	600	4800	2.80	600	200	0.10	FS
	MMF400D120U	1200	400	3600	2.10	400	190	0.085	FD

Circuit	Part Number	V _{RRM} (V)	I _{F(AV)} (A)	I _{FSM} (A)	V _{FM@I_{FM}} (V)	I _{FM} (A)	t _{rr} (ns)	R _{thJC} (K/W)	Package Outline
 <p>B</p>	MMF200S060B	600	2×200	2000	1.15	200	140	0.18	FS
	MMF300S060B	600	2×300	3000	1.15	300	150	0.14	FS
	MMF150S120B	1200	2×150	1500	1.60	150	145	0.22	FS
	MMF200S120B	1200	2×200	1800	2.30	200	110	0.22	FS
	MMF300S120B	1200	2×300	2700	2.80	300	135	0.14	FS
	MMF300N060DK6B	600	2×150	1410	1.25	150	95	0.34	FN
 <p>DK</p>	MMF200N120DK	1200	2×100	1100	1.77	100	150	0.44	FN
	MMF150S060DK	600	2×150	1500	1.15	150	130	0.22	FS
	MMF200S060DK	600	2×200	2000	1.15	200	140	0.18	FS
	MMF300S060DK	600	2×300	3000	1.15	300	150	0.14	FS
	MMF150S120DK	1200	2×150	1500	1.60	150	145	0.22	FS
	MMF200S120DK	1200	2×200	1800	2.30	200	110	0.22	FS
 <p>DA</p>	MMF300N060DA6B	600	2×150	1400	1.15	150	130	0.36	FN
	MMF200N120DA	1200	2×100	1100	1.77	100	150	0.44	FN
	MMF200N070DA	700	2×100	1200	1.20	100	140	0.34	FN
	MMF150S060DA	600	2×150	1500	1.15	150	130	0.22	FS
	MMF200S060DA	600	2×200	2000	1.15	200	140	0.18	FS
	MMF300S060DA	600	2×300	3000	1.15	300	150	0.14	FS
MMF150S120DA	1200	2×150	1500	1.60	150	145	0.22	FS	



Circuit	Part Number	V _{RRM} (V)	I _{F(AV)} (A)	I _{FSM} (A)	V _{FM@I_{FM}} (V)	I _{FM} (A)	t _{rr} (ns)	R _{thJC} (K/W)	Package Outline
 <p>D</p>	MMF2X100J040D	400	2×100	1100	1.20	100	62	0.34	FJ
	MMF2X100J060D	600	2×100	1500	1.35	100	95	0.30	FJ
	MMF2X60J120D	1200	2×60	500	1.80	60	135	0.65	FJ
	MMF2X100J120D	1200	2×60	1400	2.15	100	125	0.40	FJ
	MMF400N020DK2B	200	2×200	2000	0.90	200	135	0.34	FN
 <p>DK2B</p>	MMF400S040DK2B	400	2×400	2800	1.60	400	110	0.10	FS
	MMF150S060DK2B	600	2×150	1500	1.25	150	95	0.30	FS
	MMF200S060DK2B	600	2×200	2000	1.15	200	140	0.18	FS
	MMF300S060DK2B	600	2×300	3000	1.10	300	165	0.15	FS
	MMF200S120DK2B	1200	2×200	1800	2.30	200	110	0.22	FS
	MMF200S060DA2B	600	2×200	2000	1.15	200	140	0.18	FS
 <p>DA2B</p>	MMF300S120DA2B	1200	2×300	2700	2.80	300	135	0.14	FS
	MMF300S060DA2B	600	2×300	3000	1.10	300	165	0.15	FS
	MMF150S120B2B	1200	2×150	1500	1.60	150	145	0.22	FS
 <p>B2B</p>	MMF300S120B2B	1200	2×300	2700	2.80	300	135	0.14	FS

FRD DISCRETES

Ranges

- 300-1700V / 8-100A

Applications

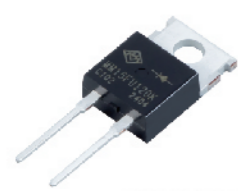
- Welding Machine
- SMPS, UPS
- Home Appliances
- Charging Pile

Packages

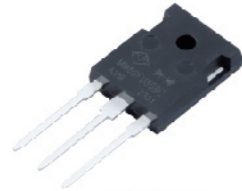
- TO-220, TO-220F
- TO-247, TO-3P

Features

- Short Recovery Time
- Soft-Recovery Characteristics
- Low Reverse Recovery Charge
- Low Leakage Current
- High Avalanche Energy



TO-220(A/B/C)



TO-247-3L



TO-3P-2L(3PN/3PB)



TO-220F

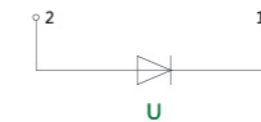
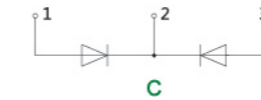


TO-247-2L



TO-3P-3L(3PN/3PB)

Circuit	Part Number	V _{RRM} (V)	I _{F(AV)} (A)	V _F (V)	t _{rr} (ns)	R _{thJC} max. (K/W)	Package Outline
<p>C</p>	MM60FU030PC	300	60	1.25	22	0.80	TO-3PN-3L
	MM60F040B	400	60	1.15	35	0.48	TO-247-2L
	MM80FU040PC	400	80	1.30	22	0.80	TO-3PN-3L
	MM30F060PC	600	30	1.41	21	0.80	TO-3PN-3L
	MM60F060PC	600	60	1.50	30	0.80	TO-3PB-3L
	MM60F060P	600	60	1.30	40	0.50	TO-3PB-2L
	MM60F060B	600	60	1.30	27	0.50	TO-247-2L
	MM30FU60K	600	30	2.00	20	0.80	TO-220C-2L
	MM75F60B	600	75	1.35	31	0.38	TO-247-2L
	MM75FU60B	600	75	2.00	25	0.38	TO-247-2L
	MM75FH60B	600	75	1.88	25	0.38	TO-247-2L
	MM75FU60B2	600	75	1.88	25	0.38	TO-247-2L
	MM30F060B	600	30	1.50	30	0.80	TO-247-2L
	MM60FU060B	600	60	2.00	25	0.50	TO-247-2L
	MM30FU060K1	600	30	2.00	20	1.50	TO-220F-2L
	MM30FU60KS	600	30	2.00	20	0.80	TO-220C-2L
	MM60FU60BC	600	60	2.00	20	0.80	TO-247-3L
	MM8FU060K	600	8	1.80	17	2.50	TO-220C-2L
	MM30FU60PC	600	30	2.00	18	1.30	TO-3PN-3L
	MM30FU060B	600	30	2.00	20	0.80	TO-247-2L
MM15F060K1	600	15	1.30	30	2.00	TO-220F-2L	
MM15F060K	600	15	1.30	30	1.50	TO-220C-2L	
MM15FU60K	600	15	2.00	18	1.30	TO-220	
MM100F60B	600	100	1.55	50	0.26	TO-247-2L	
MM100FH60B	600	100	1.60	25	0.26	TO-247-2L	
MM15F70K	700	15	1.30	21	1.50	TO-220C-2L	
MM16F70KC	700	16	1.30	19	2.50	TO-220C-3L	
MM8F70K	700	8	1.30	19	2.50	TO-220C-2L	
MM30FC100B	1000	30	2.50	25	0.80	TO-247-2L	
MM60FC100B	1000	60	2.50	30	0.40	TO-247-2L	
MM15FU120K	1200	15	2.60	25	1.50	TO-220	
MM30FU120B	1200	30	2.90	26	0.80	TO-247-2L	
MM8FU120K	1200	8	2.80	20	2.00	TO-220	
MM30FU120K	1200	30	2.90	26	0.80	TO-220	
MM60F120B	1200	60	2.10	40	0.40	TO-247-2L	
MM60FU120B	1200	60	2.80	30	0.40	TO-247-2L	
MM30FC120B	1200	30	2.80	26	0.80	TO-247-2L	
MM60FC120B	1200	60	2.80	31	0.40	TO-247-2L	
MM75F170B	1700	75	2.00	0	0.24	TO-247-2L	



RECTIFIER DIODE MODULES

Ranges

- 1600-2000V / 50-300A

Packages

- DA, DAB, DE, DEB, DF, DFB, DL, DS

Circuit Configurations

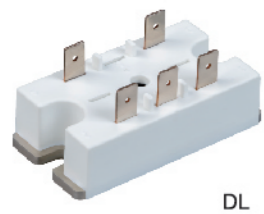
- Three Phase Rectifier Bridge Circuit
- Half Bridge Circuit
- Common-Cathode Circuit
- Single Circuit

Features

- Compact Structure
- High Current Capability
- High Blocking Voltage
- High Reliability
- High Performance Price Ratio

Applications

- Inverter
- Switching Mode Power Supply
- Welding Machine
- Medical Power Supply



DL



DE



DEB



DFB



DF



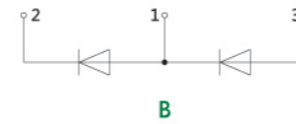
DA



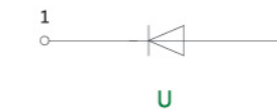
DAB



DS



B



U

Circuit	Part Number	V _{RRM} (V)	I _{F(AV)} (A)	I _{FSM} (A)	V _{FM} @ I _{FM} (V)	R _{thJC} (K/W)	Package Outline
	MMD110A180B	1800	110	2500	1.60	350	DA
	MMD130A160B	1600	130	3450	1.50	400	DA
	MMD130A180B	1800	130	3500	1.50	400	DA
	MMD110AB160B	1600	110	2350	1.40	300	DAB
	MMD160AB160B	1600	160	5000	1.50	500	DAB
	MMD130S160B	1600	130	3500	1.50	400	DS
	MMD160S160B	1600	160	5500	1.50	500	DS
	MMD160S180B	1800	160	5500	1.50	500	DS
	MMD180S180B	1800	180	6000	1.50	600	DS
	MMD200S180B	1800	200	6500	1.50	600	DS
	MMD240S160B	1600	240	7350	1.55	600	DS
	MMD300S160U	1600	300	9000	1.25	500	DS



Circuit	Part Number	V_{RRM} (V)	$I_{F(AV)}$ (A)	I_{FSM} (A)	$V_{F(max)}@I_F$ (V)	R_{thJC} (K/W)	Package Outline
X	MMD50L160X	1600	50	500	1.40	50	DL
	MMD70E160X	1600	70	700	1.35	70	DE
	MMD70E180X	1800					
MMD70E200X	2000						
X	MMD100E160X	1600	100	1000	1.35	100	DE
	MMD100E180X	1800					
	MMD100E200X	2000					
X	MMD100F200X	2000	100	1000	1.35	100	DF
	MMD150F160X	1600	150	1500	1.45	150	DF
		MMD150F180X					
X	MMD160F200X	2000	160	1600	1.50	160	DF
	MMD200F160X	1600	200	2000	1.45	200	DF
		MMD200F180X					
X	MMD200F200X	2000	250	2500	1.55	250	DF
	MMD250F160X	1600					
	MMD250F180X	1800					
X	MMD100EB160X	1600	100	1000	1.35	100	DEB
	MMD150FB160X	1600	150	1500	1.45	150	DFB
		MMD200FB160X					
X	MMD250FB160X	1600	200	2000	1.45	200	DFB
		MMD250FB180X					
	MMD250FB180X	1800	250	2500	1.55	250	DFB

EMERGING INDUSTRY APPLICATIONS

AI DATA CENTER POWER SUPPLY



IGBT MODULES

Circuit	Part Number	V_{RRM} (V)	$I_{F(AV)}$ (A)	Package Outline
B	MMG300D120B6TC	1200	300	GD
	MMG300WB120B6TC	1200	300	GWB
PD	MMG400D120B6TC	1200	400	GD
	MMG450D120B6TC	1200	450	GD
UZ	MMG450WQ120PD6T7	1200	450	GWQ
	MMG450WQ120PD6T7H	1200	450	GWQ
URB	MMG300D170B6TC	1700	300	GD
	MMG300WB170B6TC	1700	300	GWB
URB	MMG450WB170B6TC	1700	450	GWB
	MMG600WB170B6T6	1700	600	GWB
URB	MMG800QE170URB6T6	1700	800	GQE
	MMG800QF170URC6T6	1700	800	GQF



◆ SiC POWER DEVICES

Circuit	Part Number	V _{DSS} (V)	R _{DS(ON)} (mΩ)	Package Outline
	MMN4CE120BA4P6BS	1200	4	NCE
	MMN07D170BC3P6BS_F	1700	7	ND
	MML13N3S120BK	1200	13	TO-247-4L

◆ GAN HEMT POWER DEVICES

Circuit	Part Number	V _{DSS} (V)	R _{DS(ON)} (mΩ)	Package Outline
	ASL025HG65TL	650	25	TOLL
	ASL030HG65TL	650	30	TOLL
	ASL050HG65TL	650	50	TOLL

HUMANOID ROBOTS



Type	Technology	Configuration	Package	V _{DS} max (V)	R _{DS(on)} typ (mΩ)	R _{DS(on)} max (mΩ)	Q _{oss} (nC)	ID max (A)	ID pulse max (A)
ASL010HG10WB	Gen 1	Single	WLCSP 4.15X6.8	100	8	10	48	16	130
ASL007HG10WB	Gen 1	Single	WLCSP 2.5X1.5	100	5.5	7	25	19	137
ASL004H2G10WB	Gen 2	Single	WLSCP 2.5x1.5	100	3.1	4	27	29	165
ASL002H2G10QX	Gen 2	Single	QFN 5x3	100	1.7	2.3	71	58	453

LOW-ALTITUDE ECONOMY

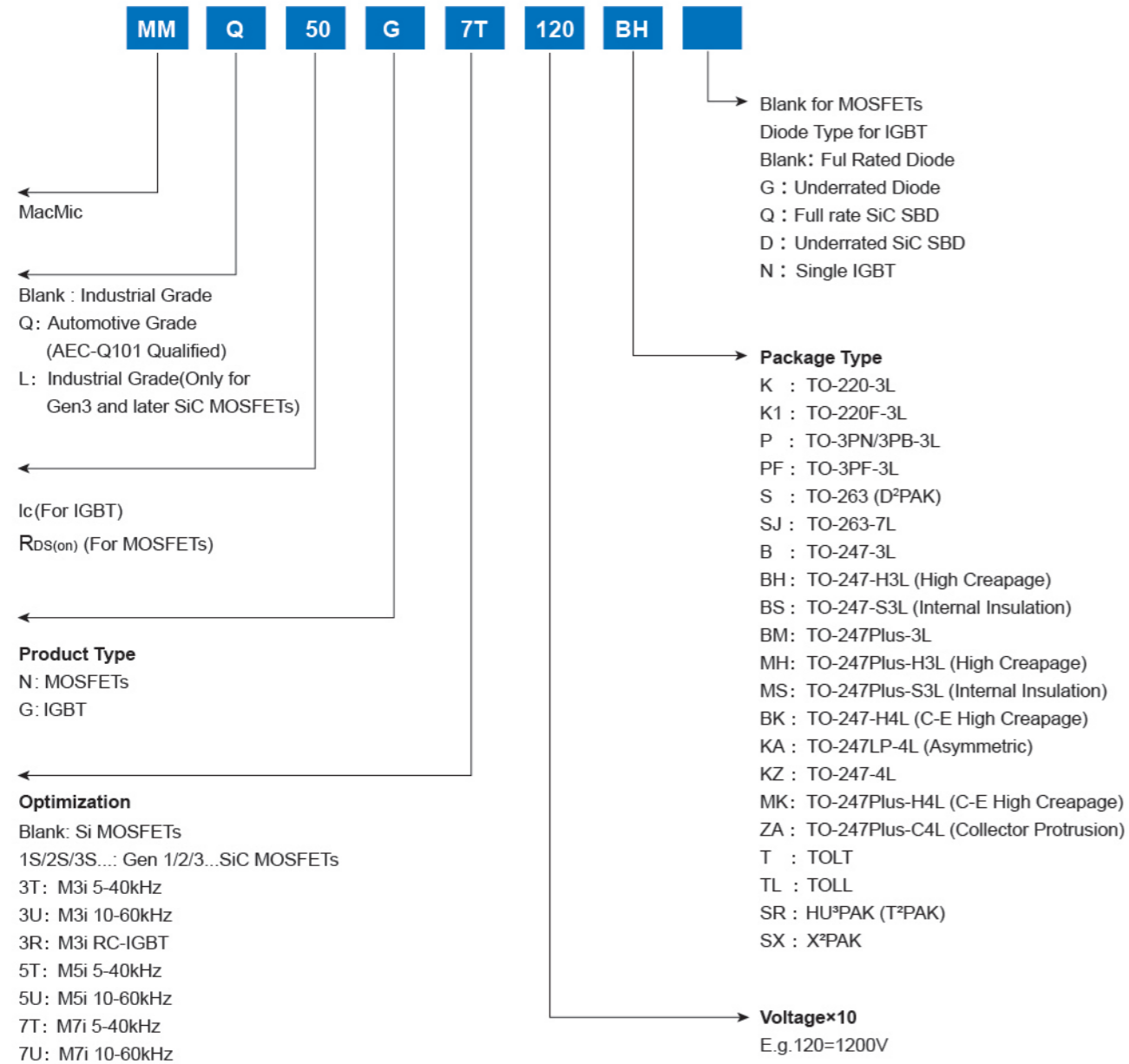


CONTROLLED NUCLEAR FUSION

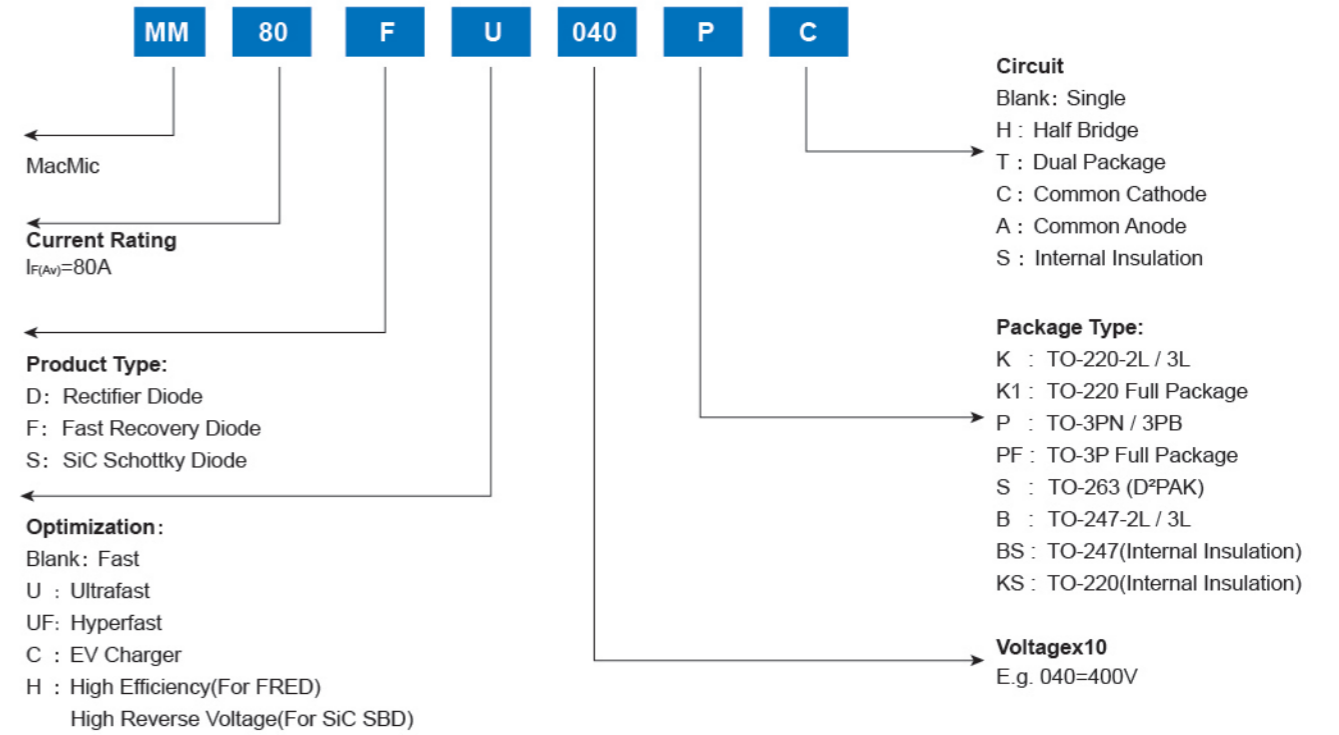


PRODUCT NAMING

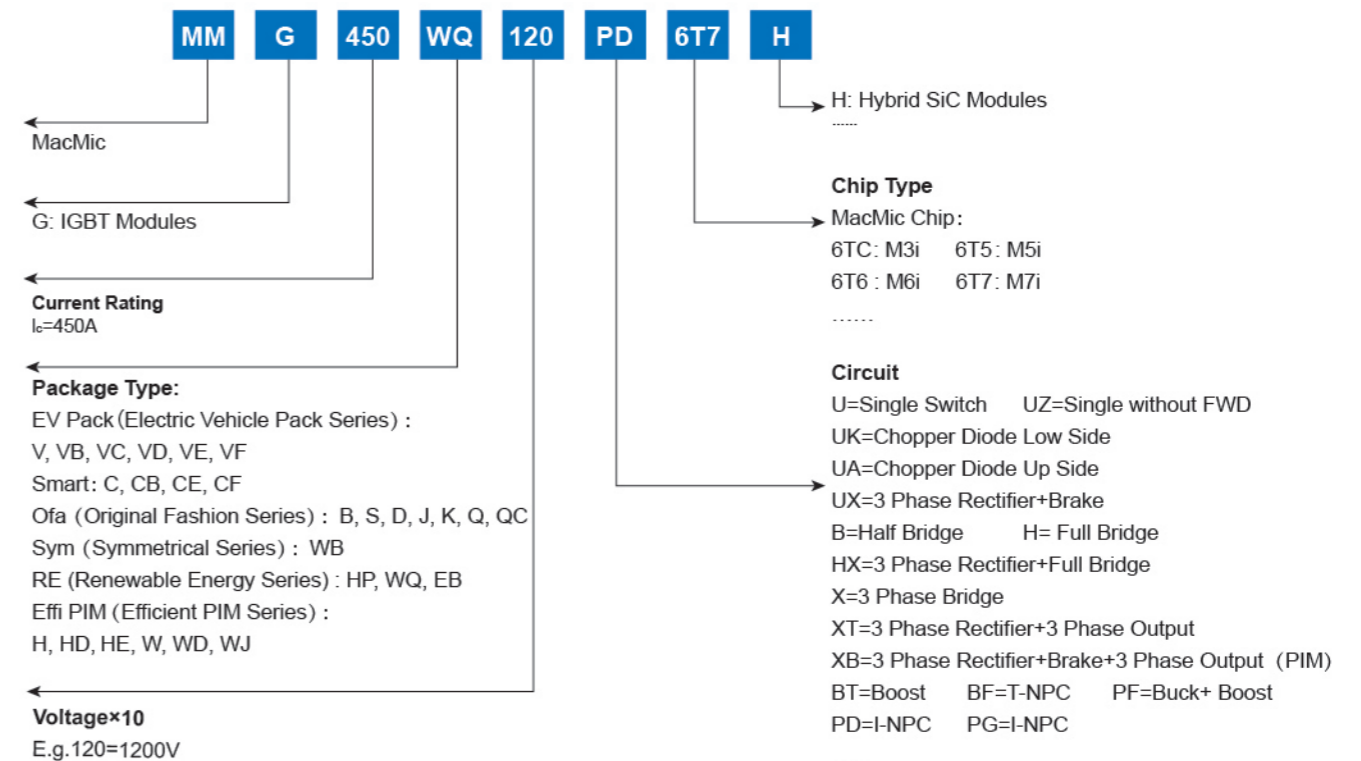
IGBT & MOSFET & SiC MOSFET DISCRETES



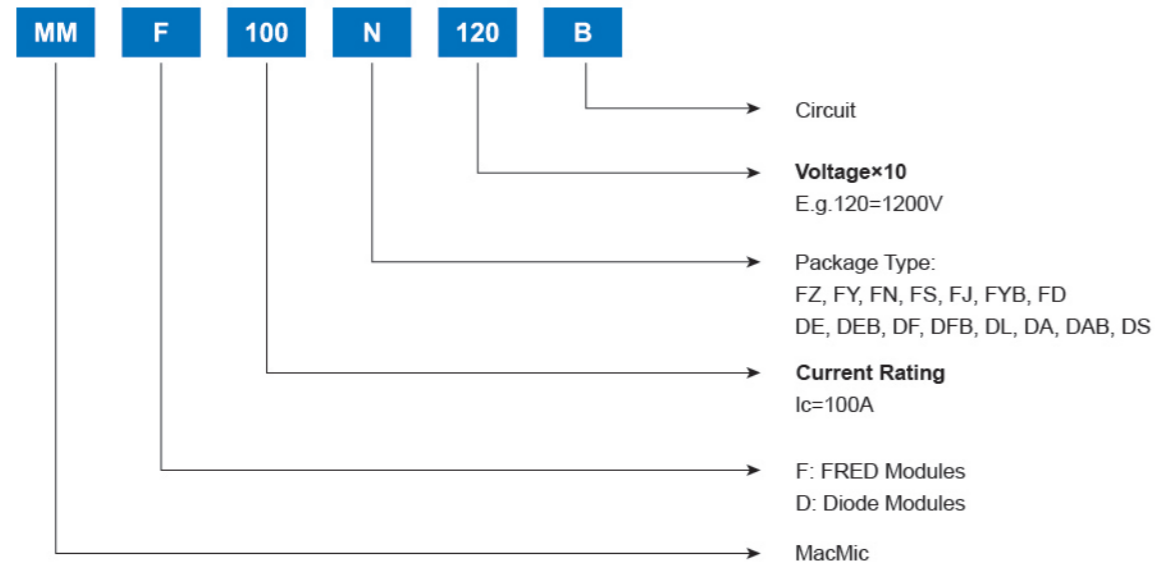
FRD & SiC SBD DISCRETES



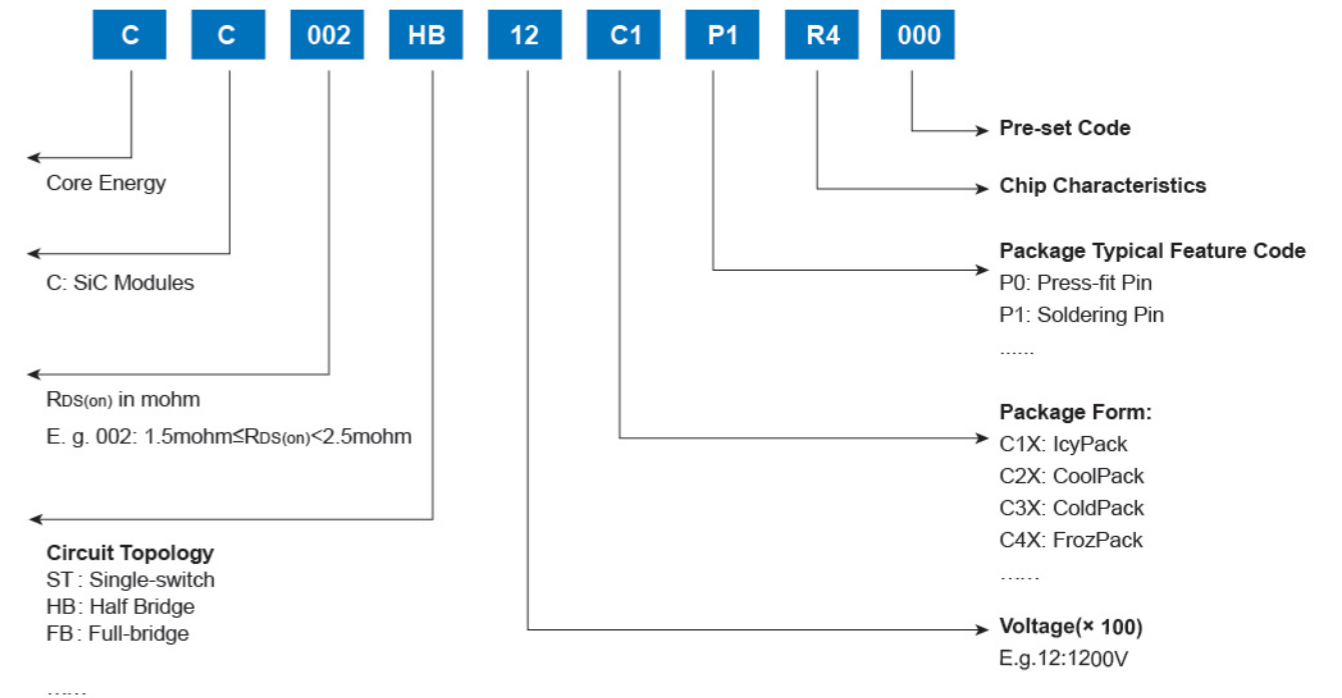
IGBT MODULES & HYBRID SiC MODULES



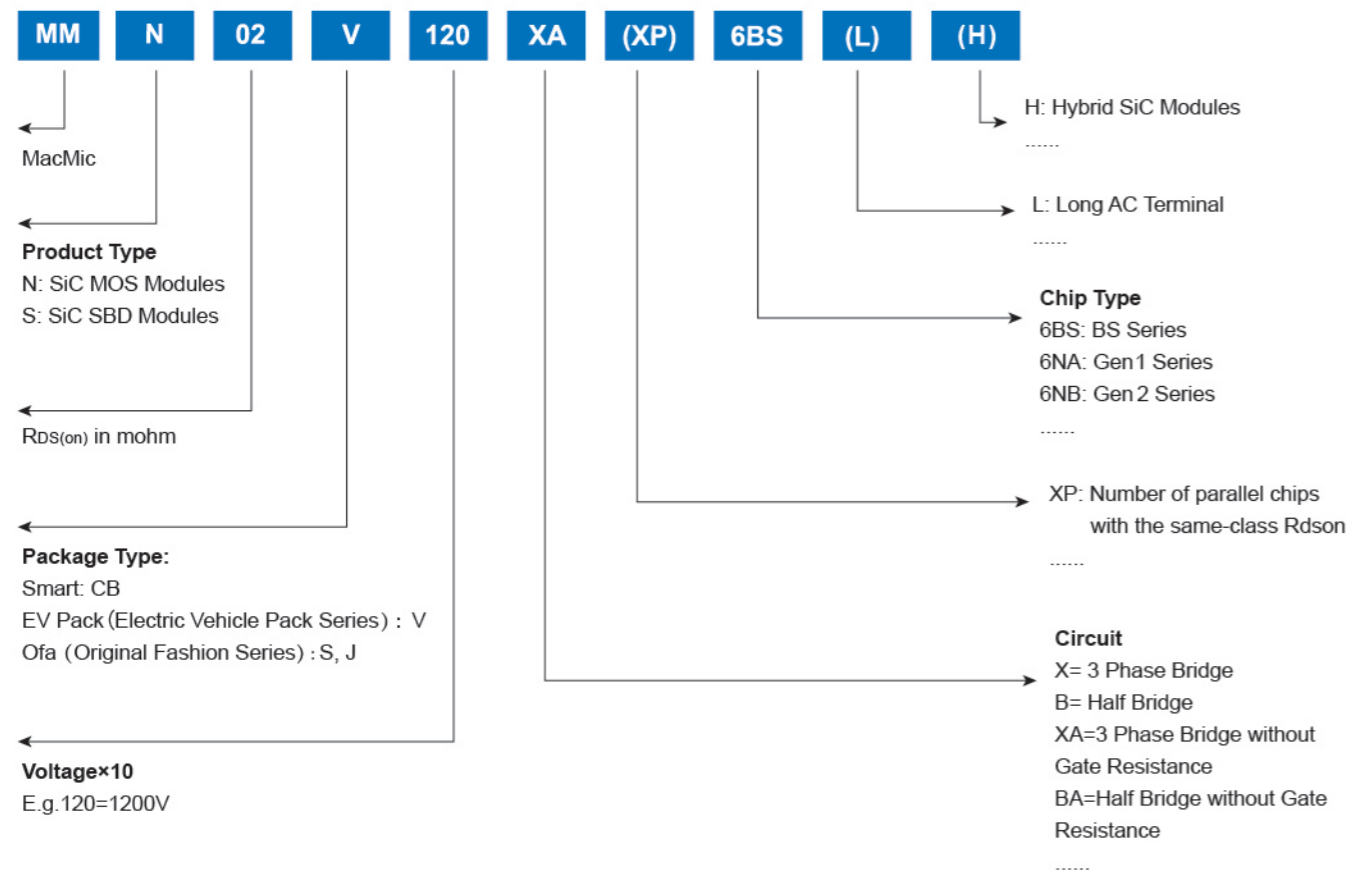
FRD MODULES / RECTIFIER DIODE MODULES / THREE-PHASE RECTIFIER BRIDGE MODULES



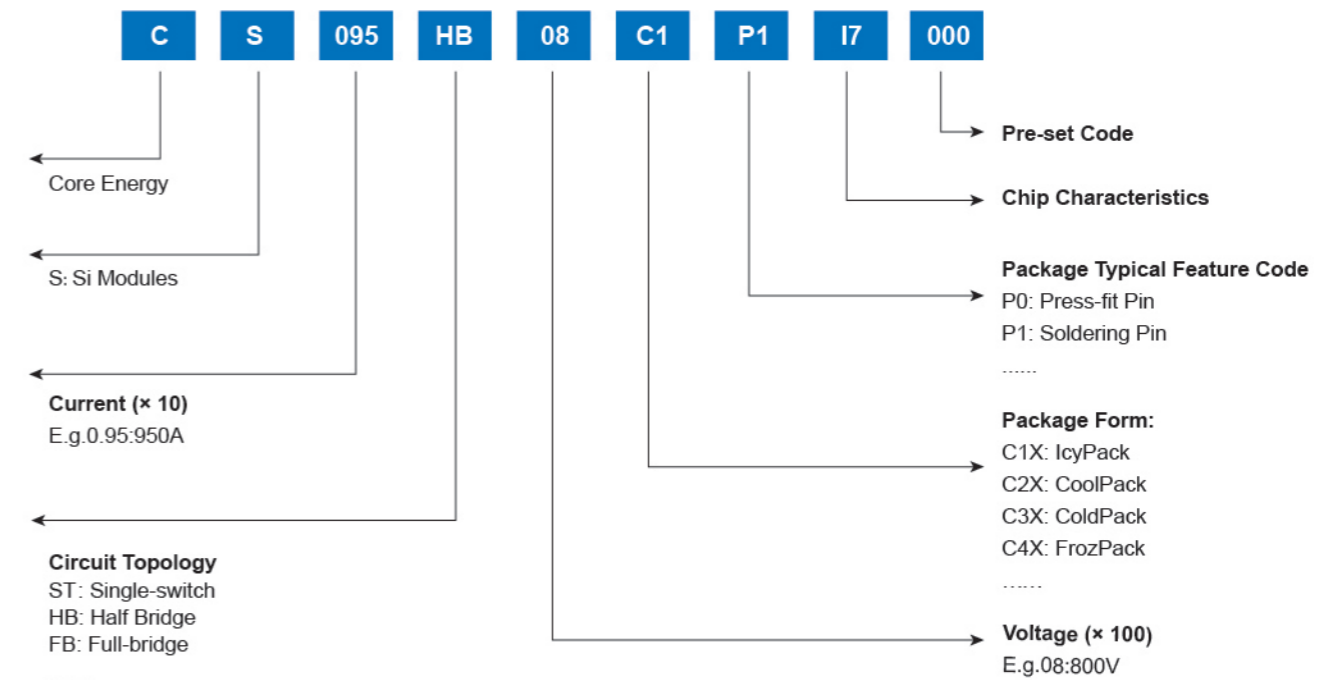
TRANSFER-MOLDED SiC MODULES



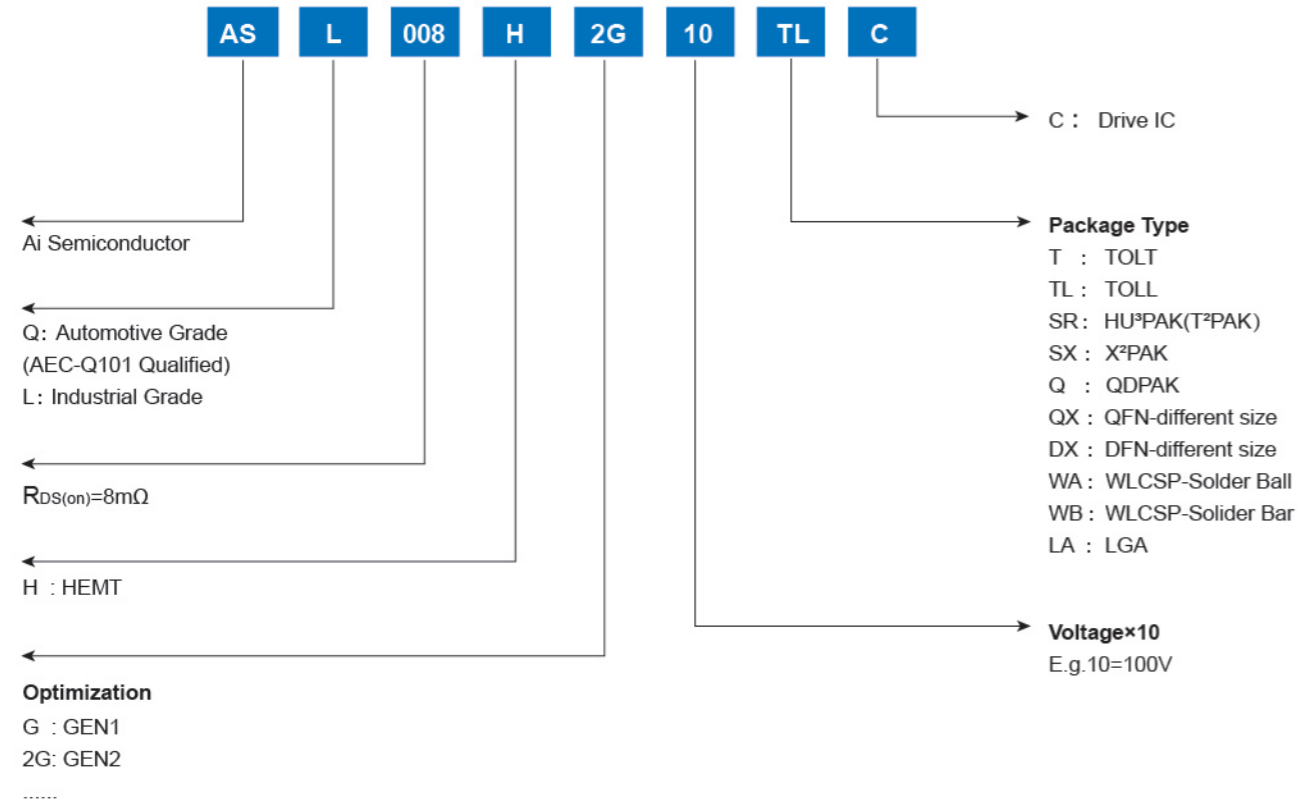
SiC MOSFET MODULES



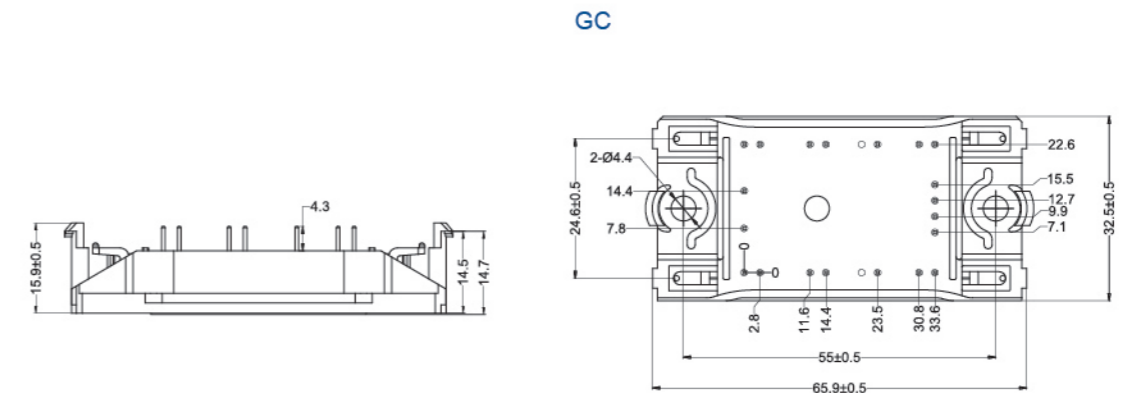
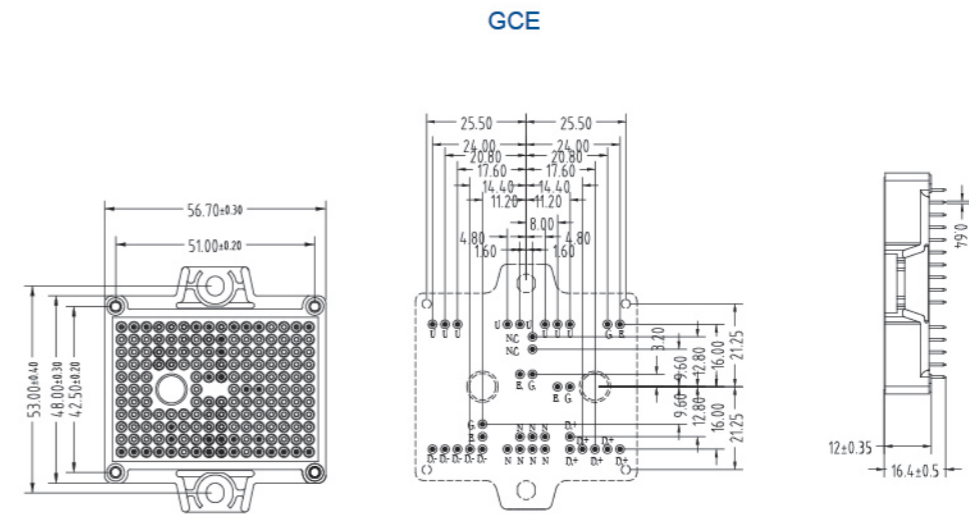
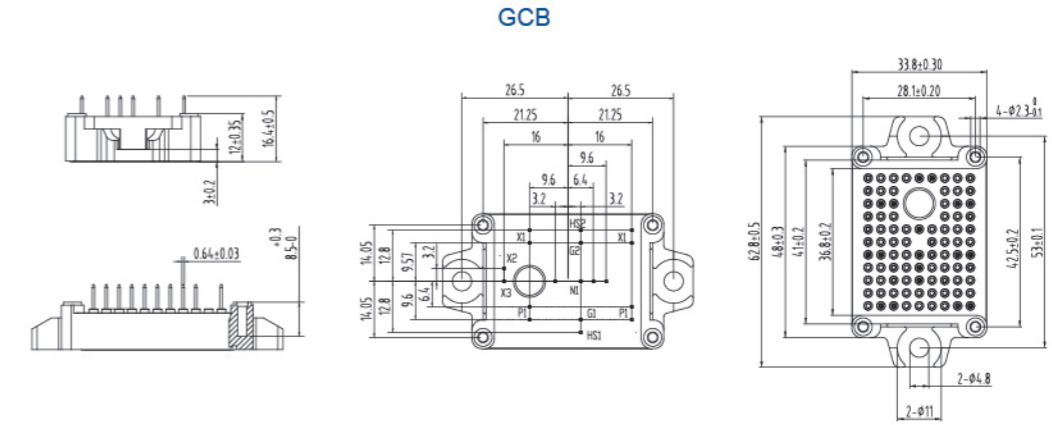
TRANSFER-MOLDED IGBT MODULES



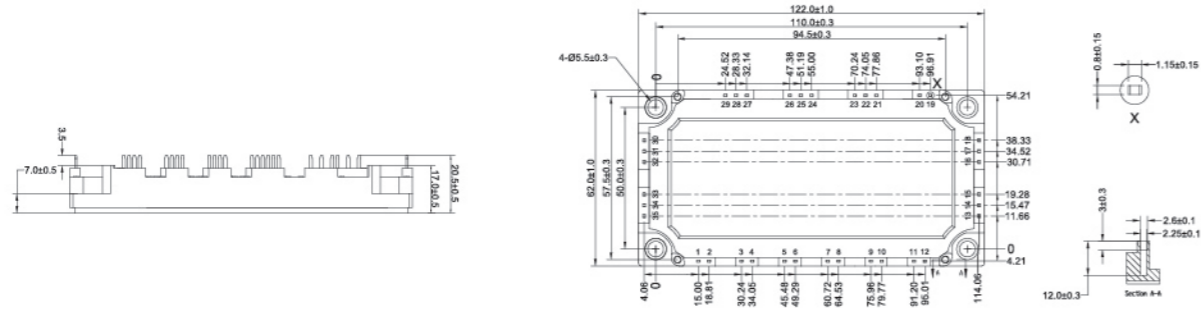
GaN HEMT POWER DEVICES



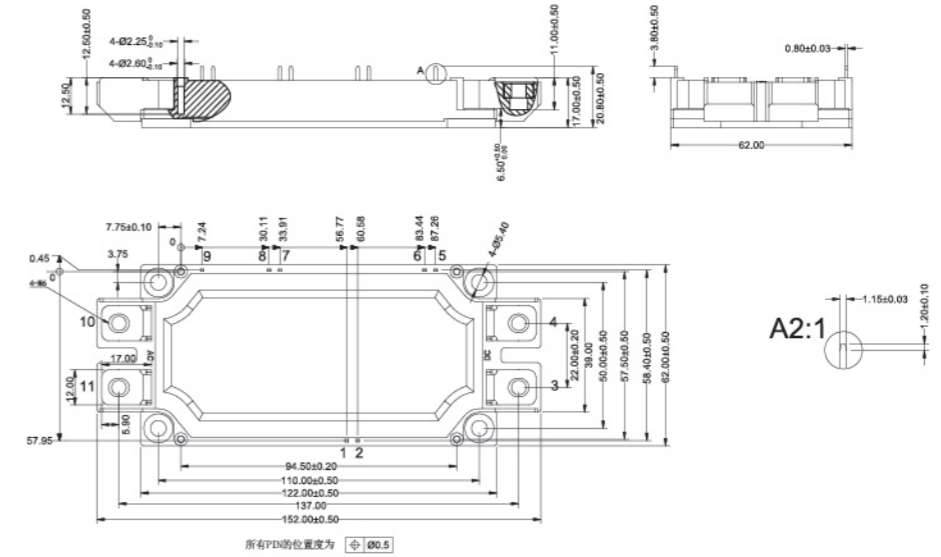
OUTLINE DRAWINGS



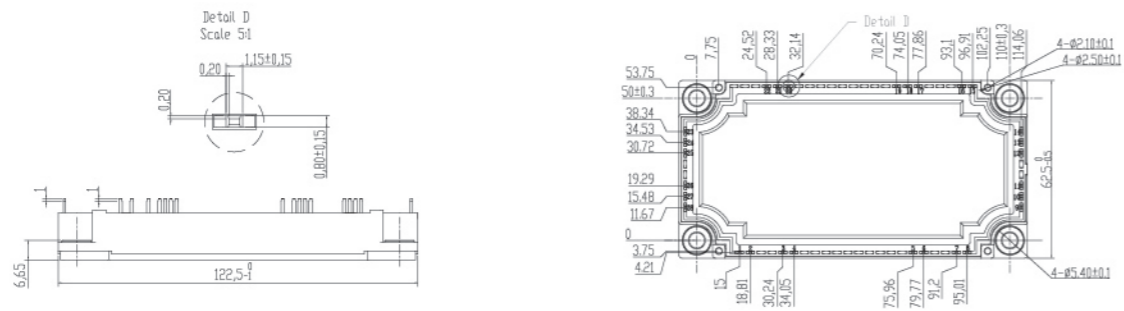
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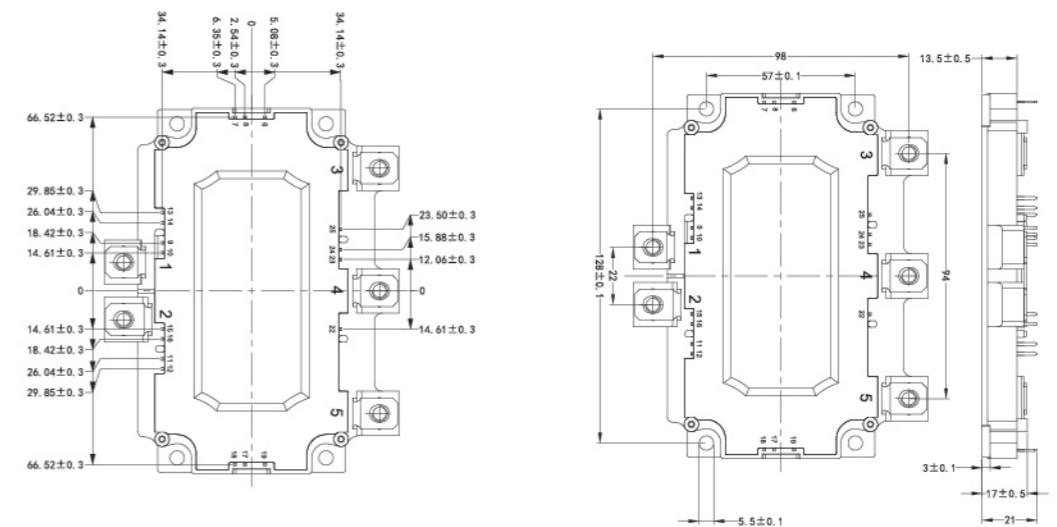
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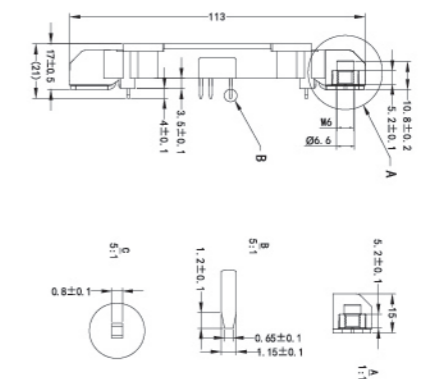
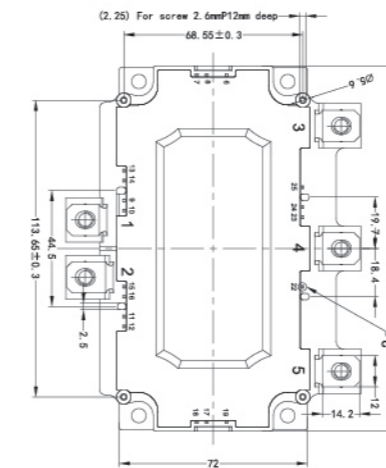
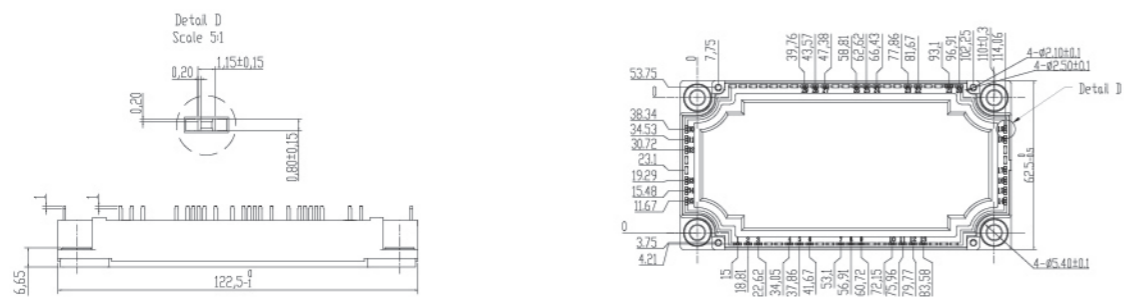
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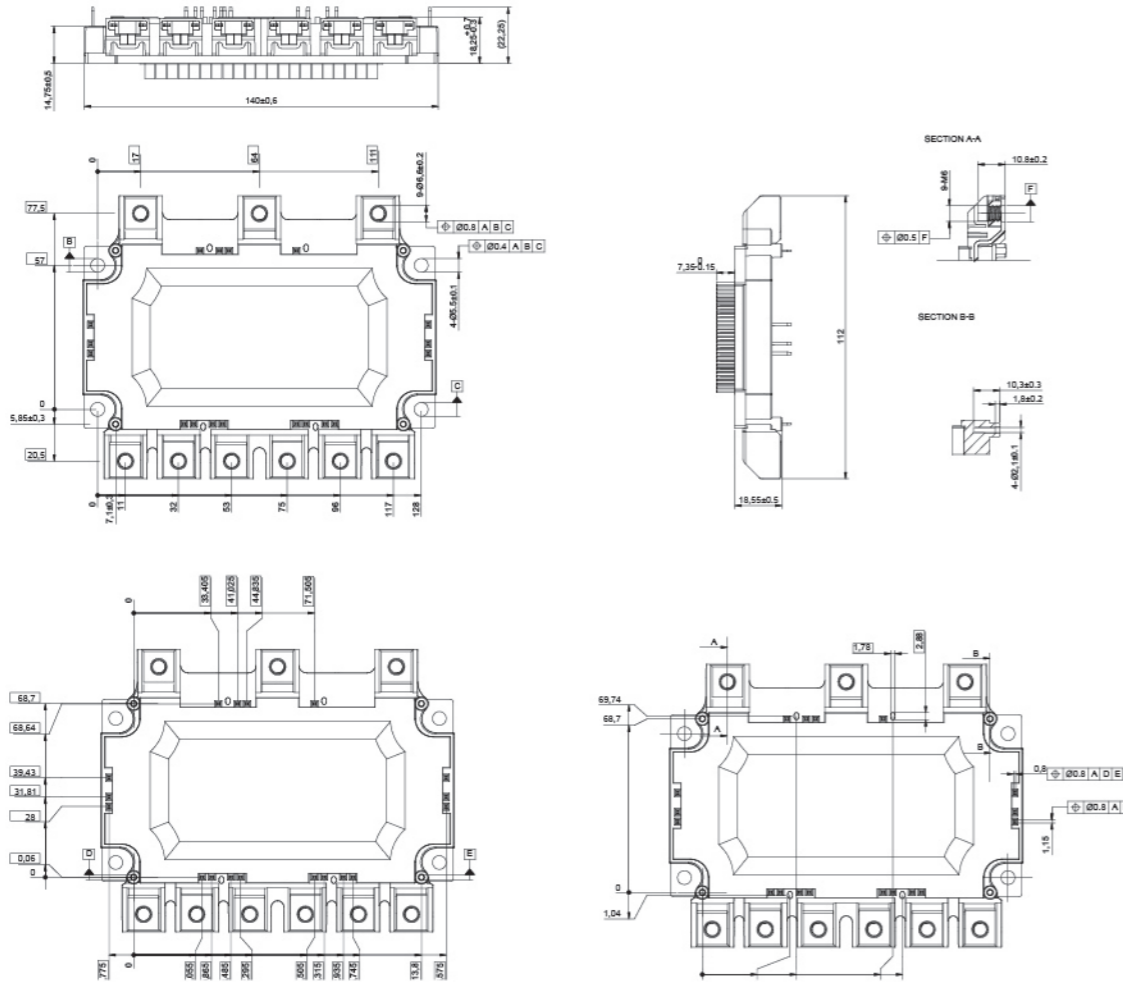
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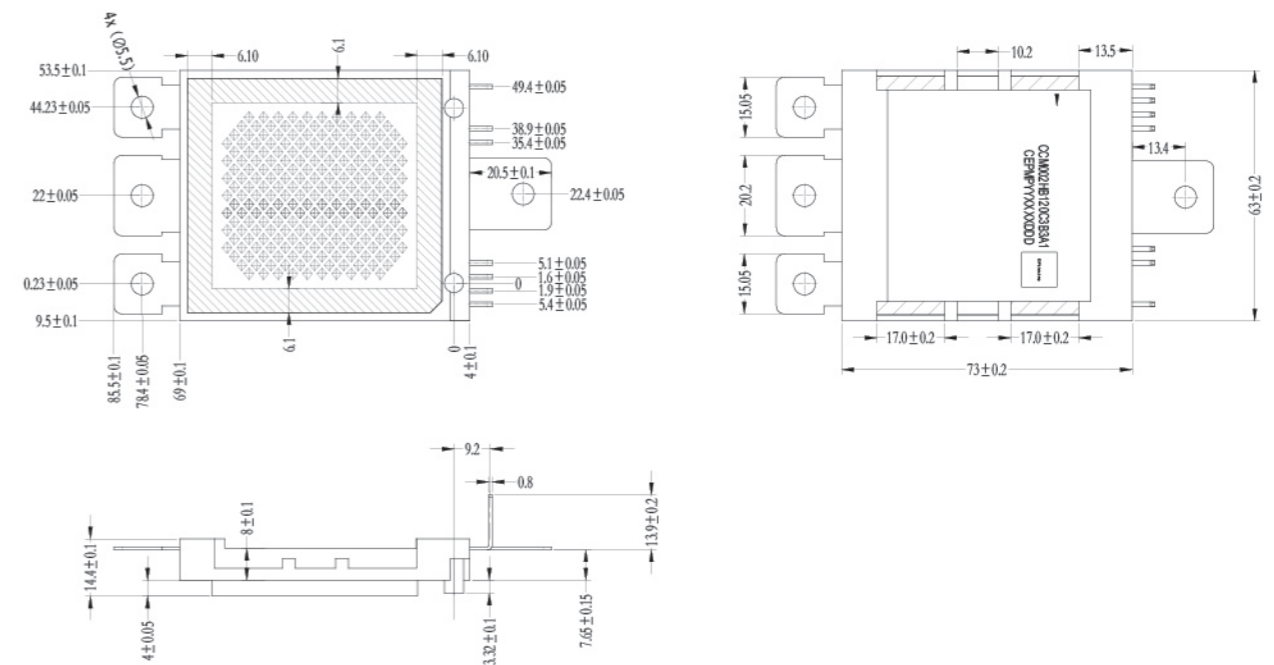
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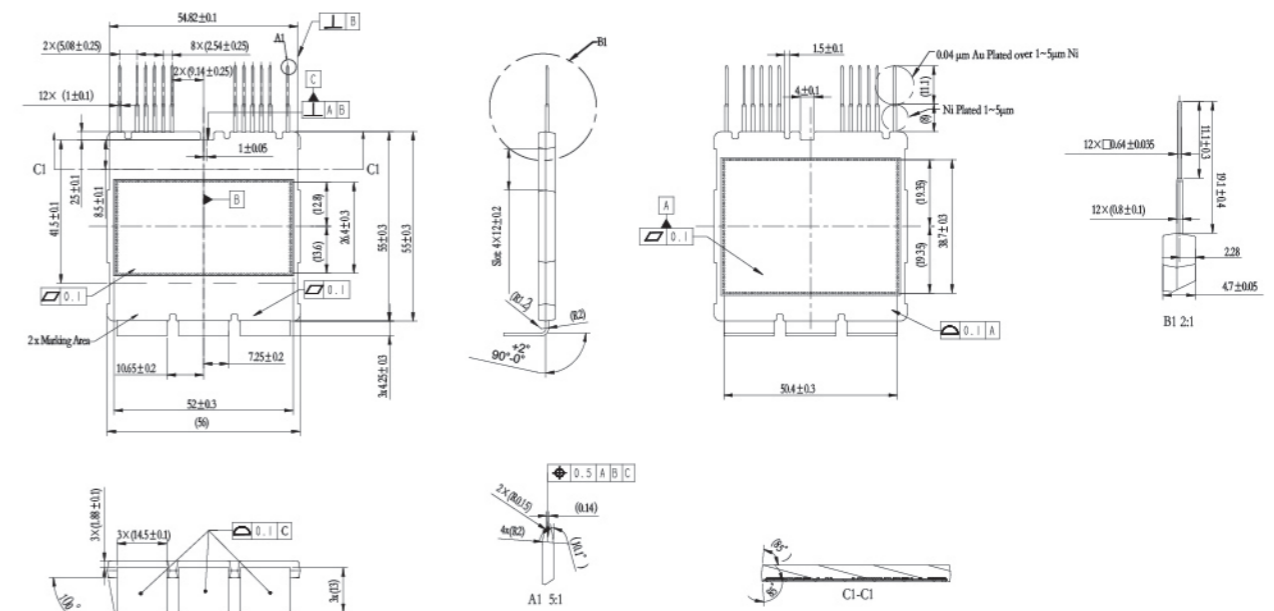
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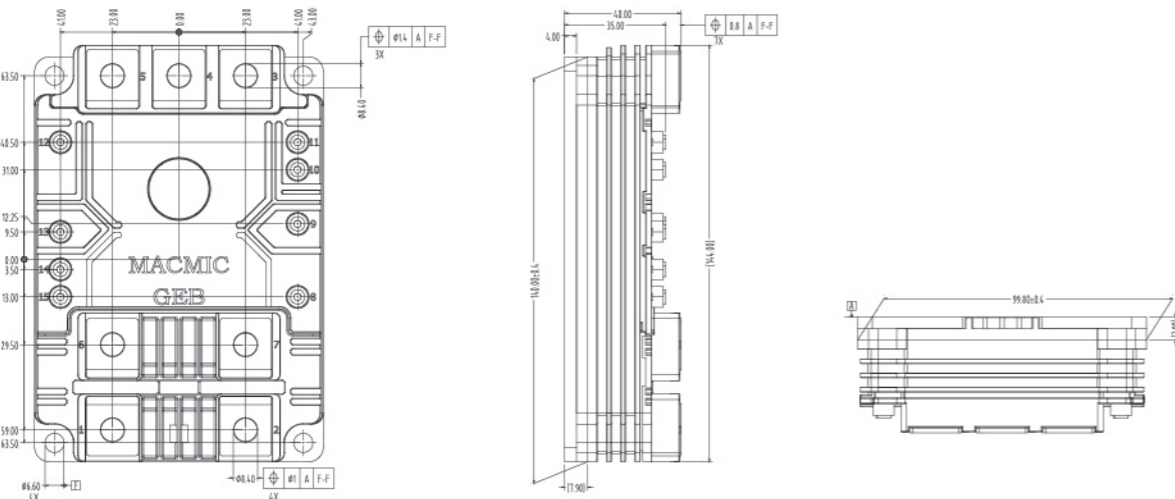
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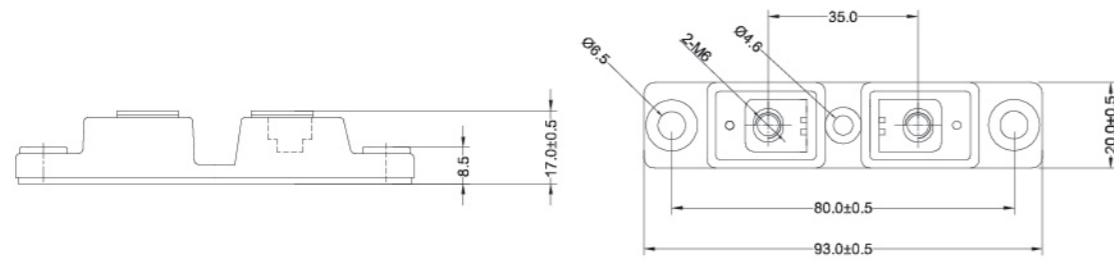
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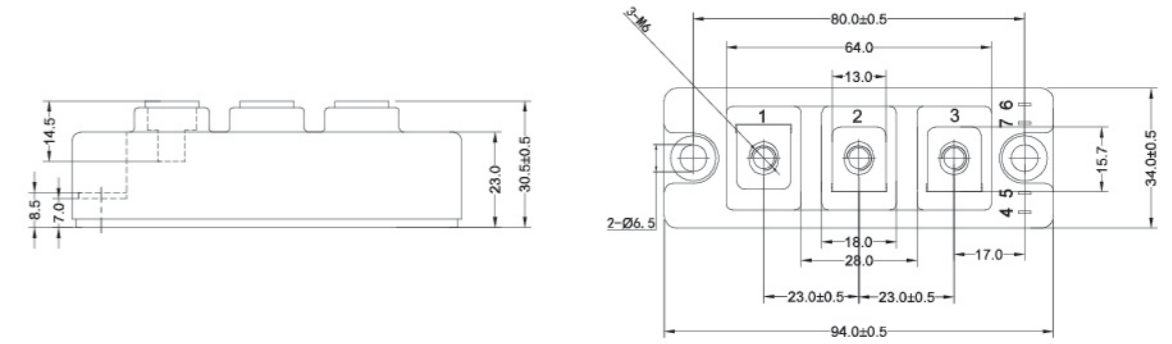
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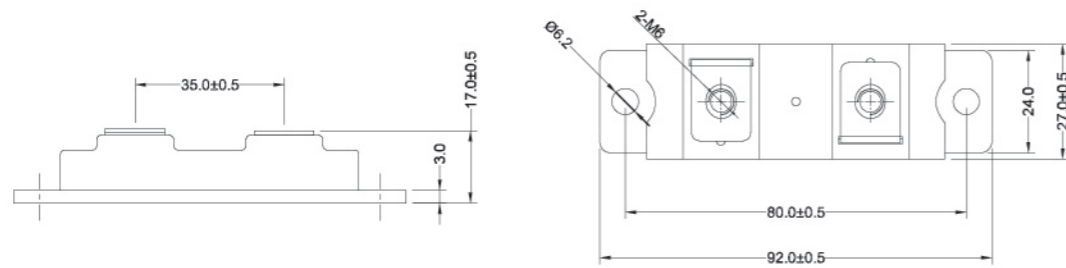
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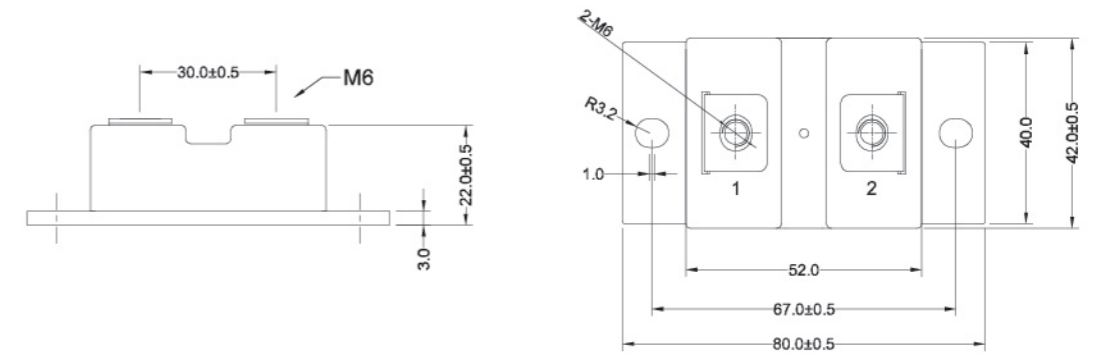
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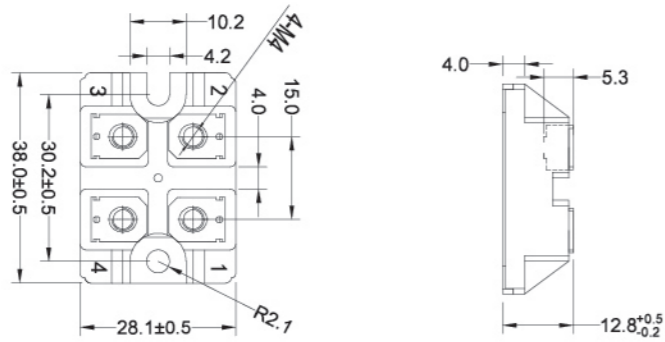
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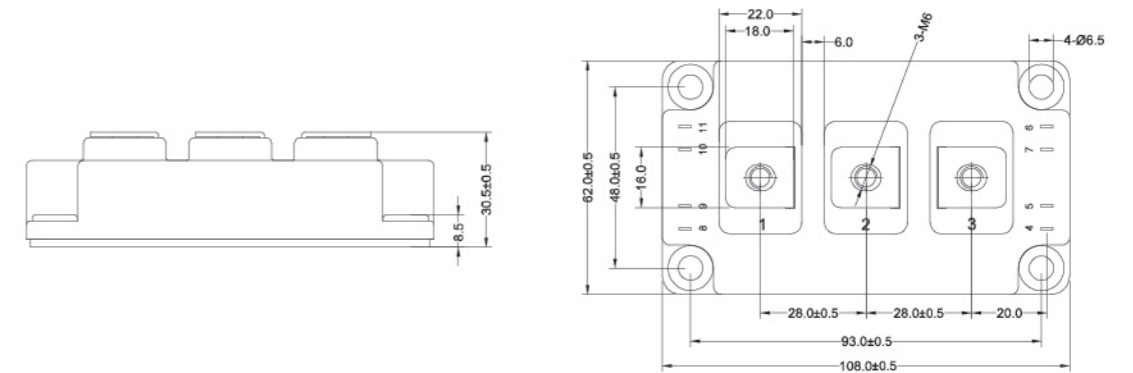
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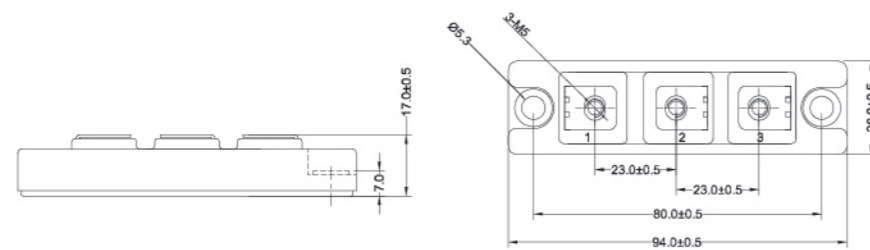
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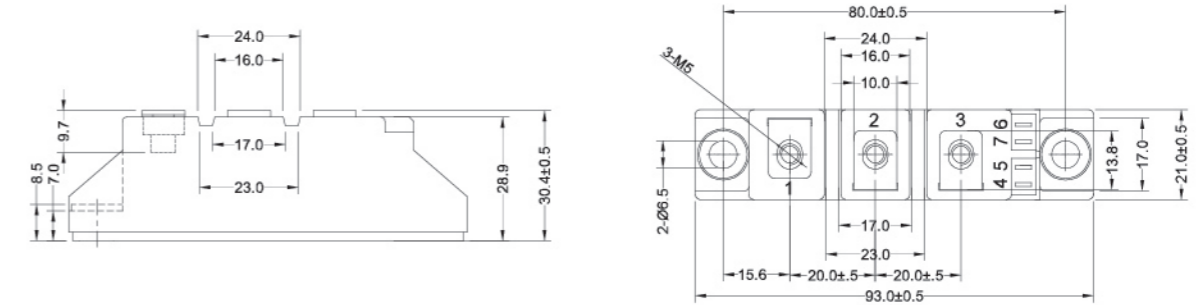
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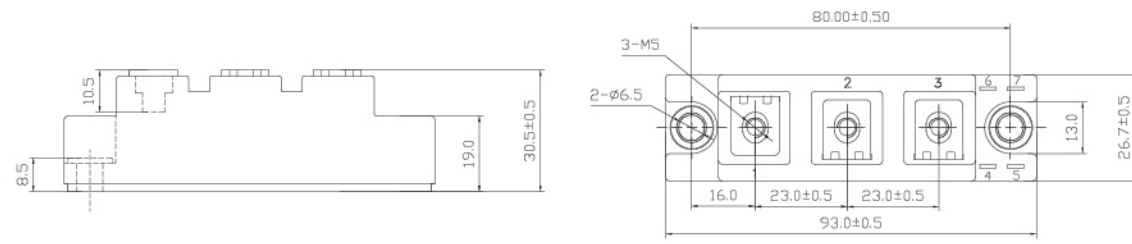
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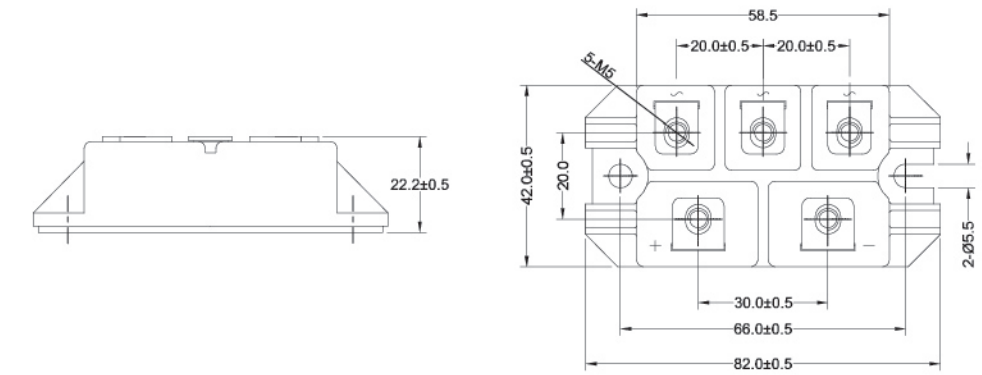
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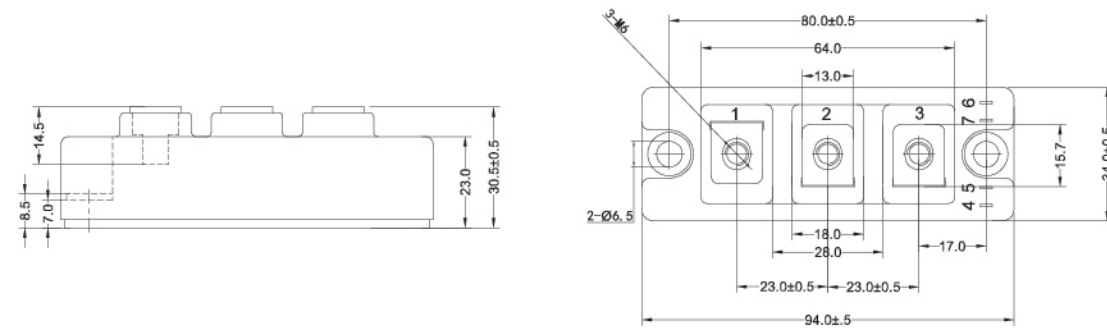
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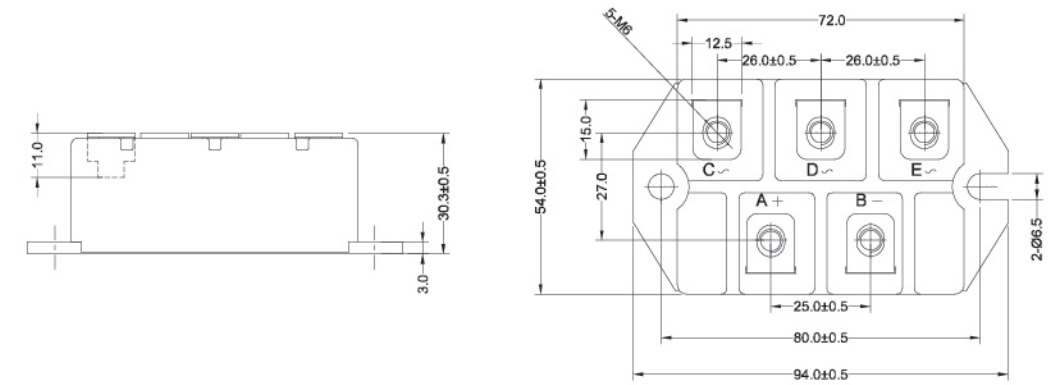
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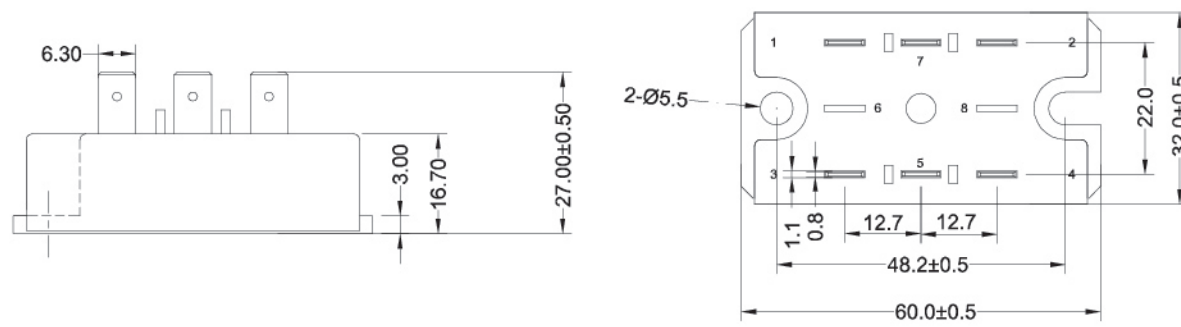
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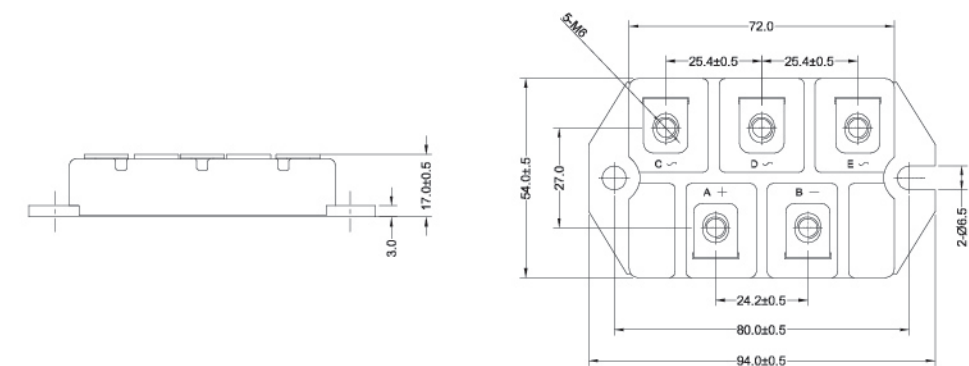
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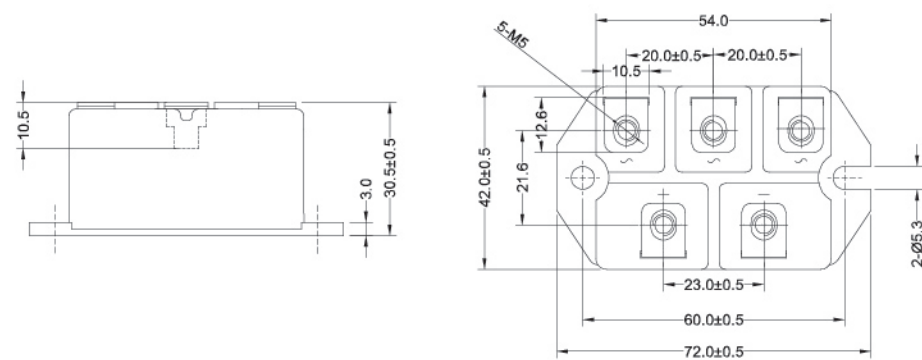
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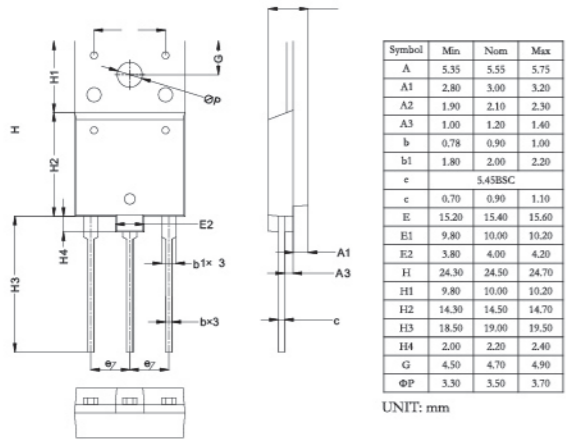
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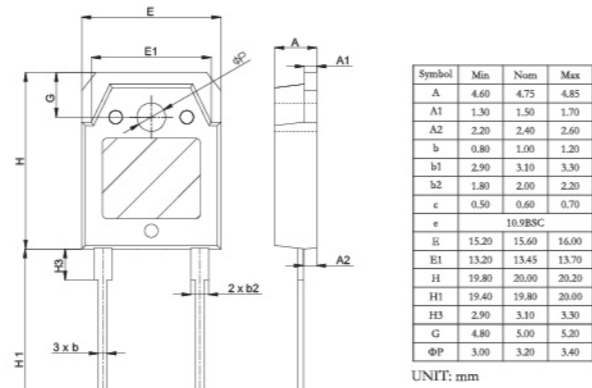
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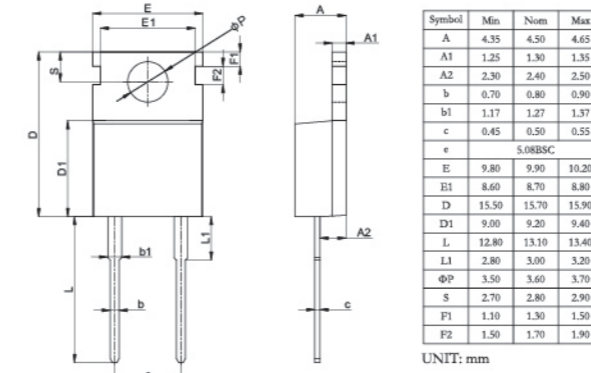
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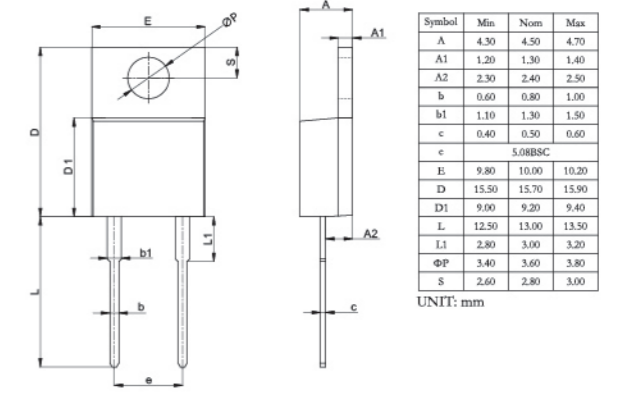
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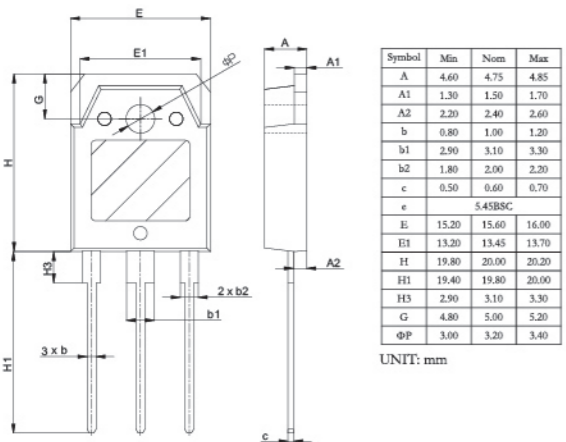
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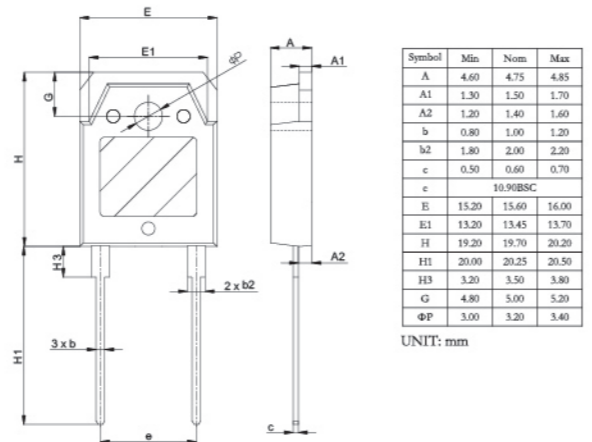
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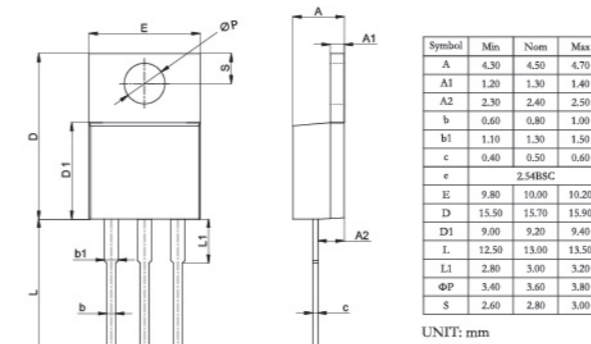
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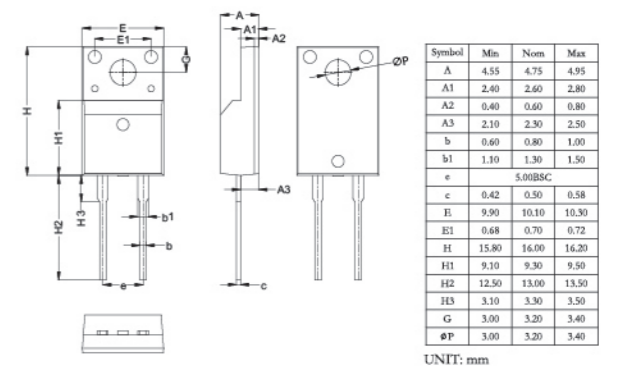
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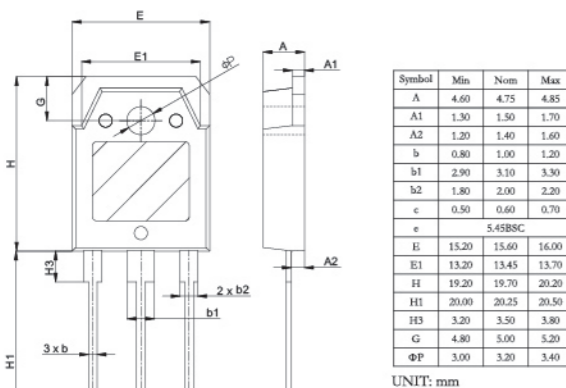
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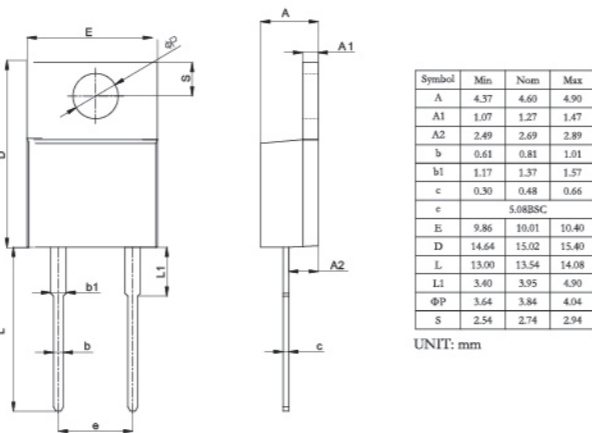
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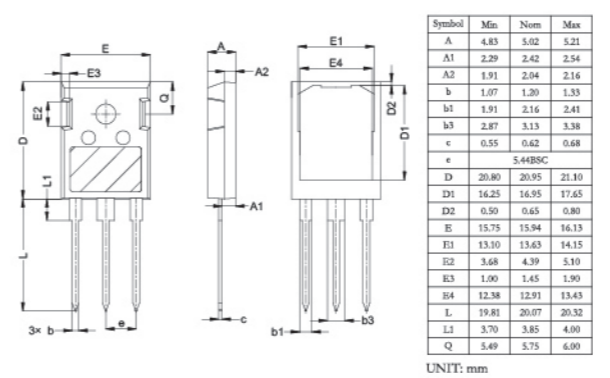
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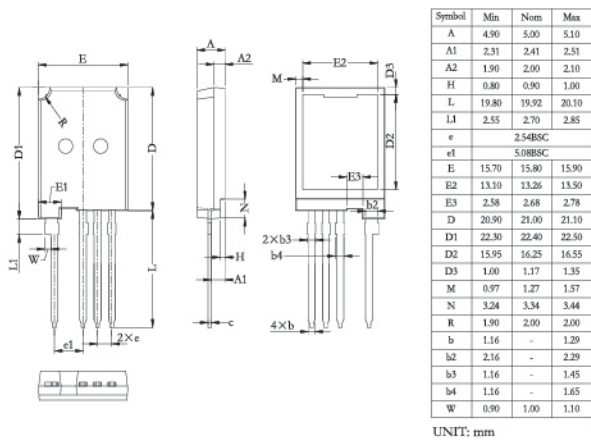
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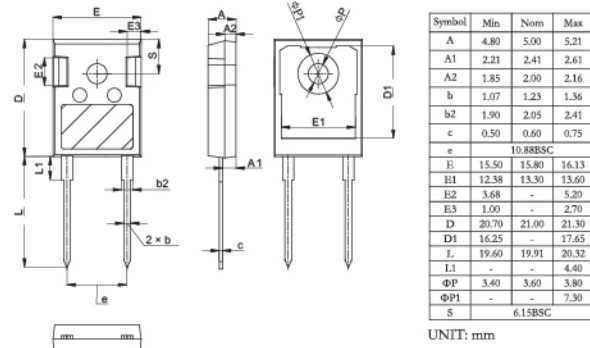
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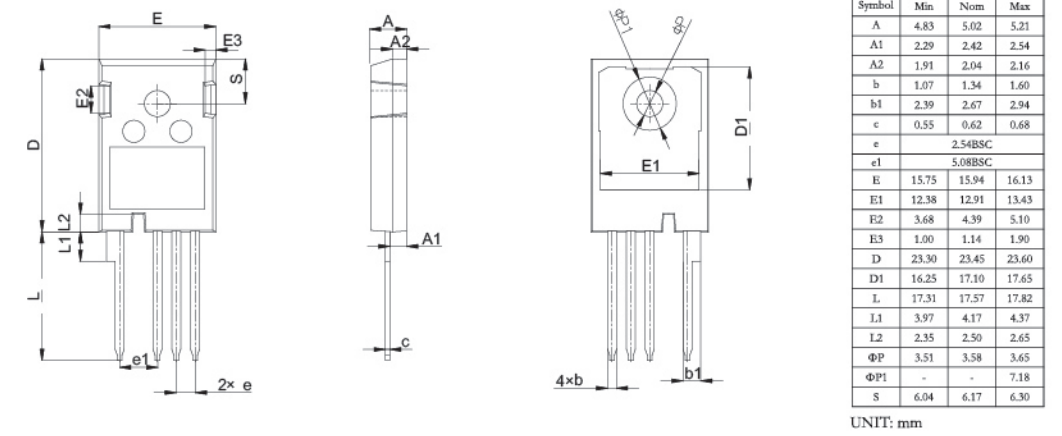
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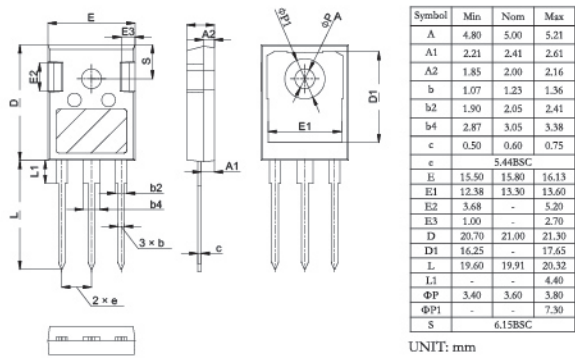
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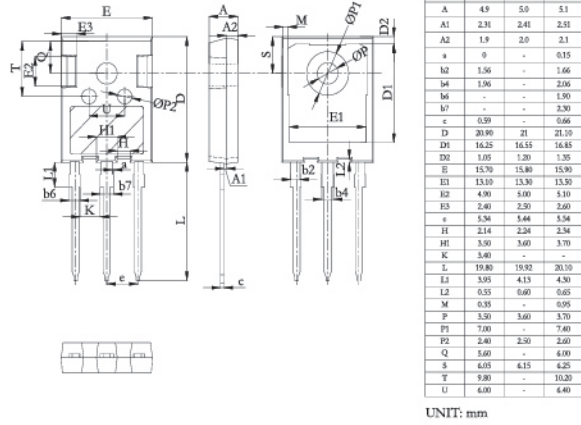
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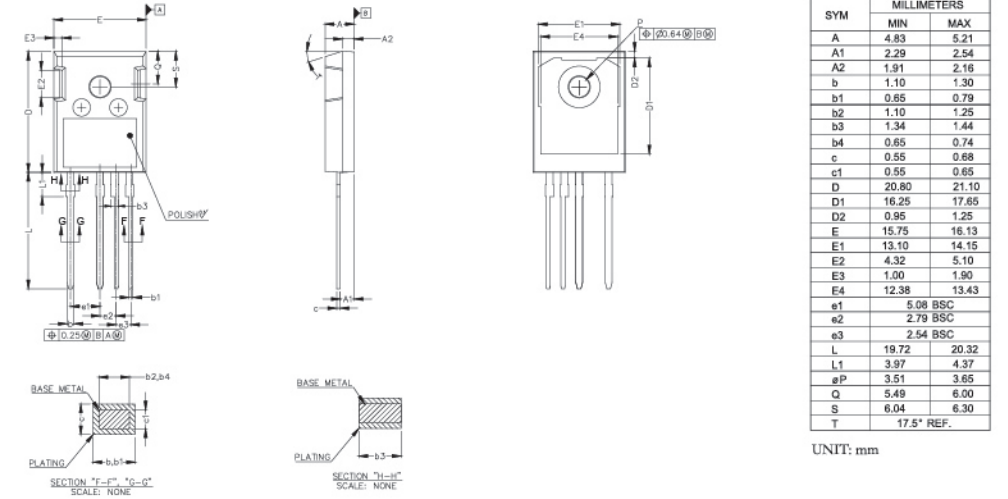
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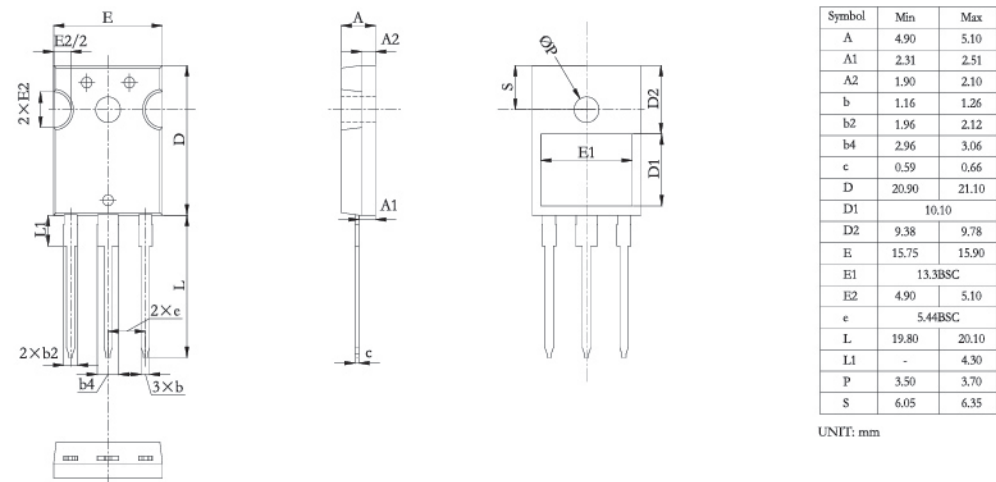
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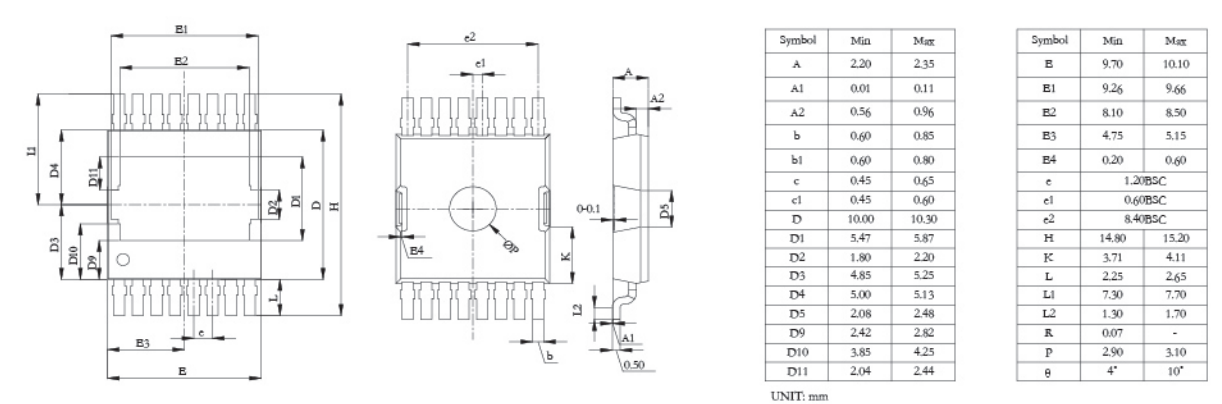
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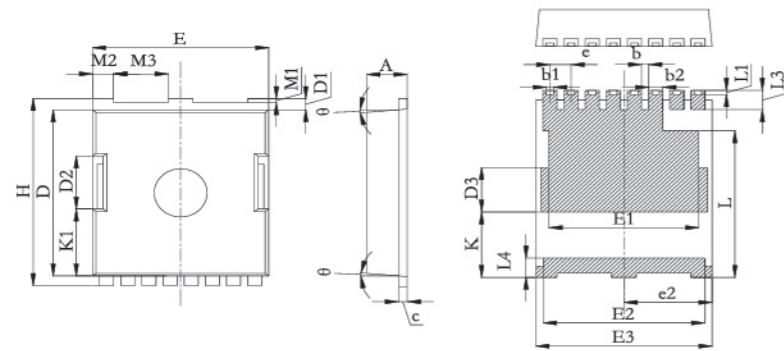
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TOLT



TOLL



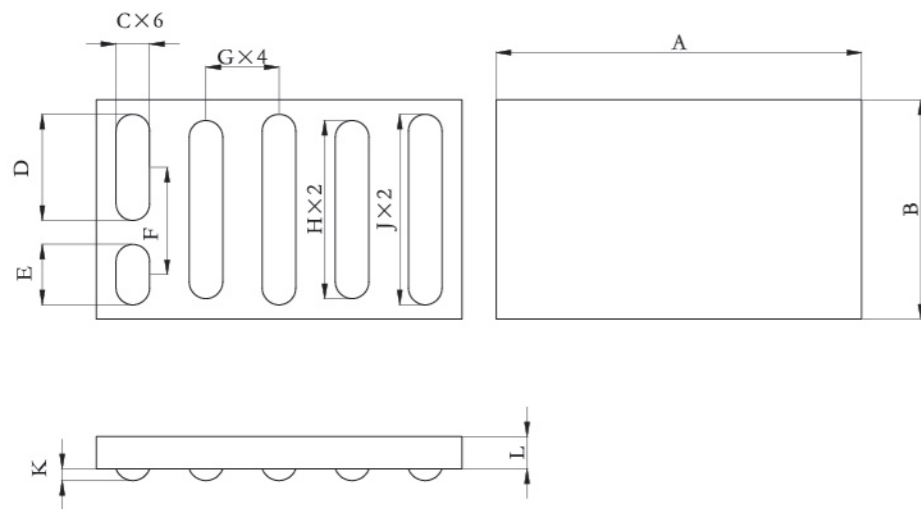
Symbol	Min	Max
A	2.20	2.40
b	0.30	0.50
b1	0.35	0.55
b2	0.70	0.90
c	0.40	0.60
D	10.28	10.58
D1	0.60	0.80
D2	(3.30)	
D3	(2.77)	
E	9.70	10.10
E1	(8.50)	
E2	(8.50)	
E3	(9.46)	
e	1.10	1.30

Symbol	Min	Max
H	11.48	11.88
K	(4.08)	
K1	(4.17)	
L	(9.13)	
L1	0.13	0.33
L2	0.50	0.70
L3	1.10	1.30
L4	1.10	1.30
M	(4.23)	
M1	0.16	0.36
M2	1.10	1.30
M3	3.00	3.20
θ	4°	10°
e2	4.20	4.40

UNIT: mm

UNIT: mm

WLCSP 4.15X4.4



Symbol	Min	Max
A	2475	2525
B	1475	1525
C	210	250
D	707	747
E	394	434
F	724	744
G	500 BSC	
H	1199	1239
J	1284	1324
K	70	90
L	205	235

UNIT: mm

Unit:mm

